

# **PFE1000FA**

# **EVALUATION DATA**

## **型式データ**

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## 使用記号 Terminology used

定義 Definition			
Vin	.....	入力電圧	Input voltage
Vo	.....	出力電圧	Output voltage
Vonoff	.....	+ON/OFF電圧	+ON/OFF voltage
Iin	.....	入力電流	Input current
Io	.....	出力電流	Output current
Tbp	.....	ベースプレート温度	Base plate temperature
Ta	.....	周囲温度	Ambient temperature
f	.....	周波数	Frequency

※ 当社測定条件における結果であり、参考値としてお考え願います。

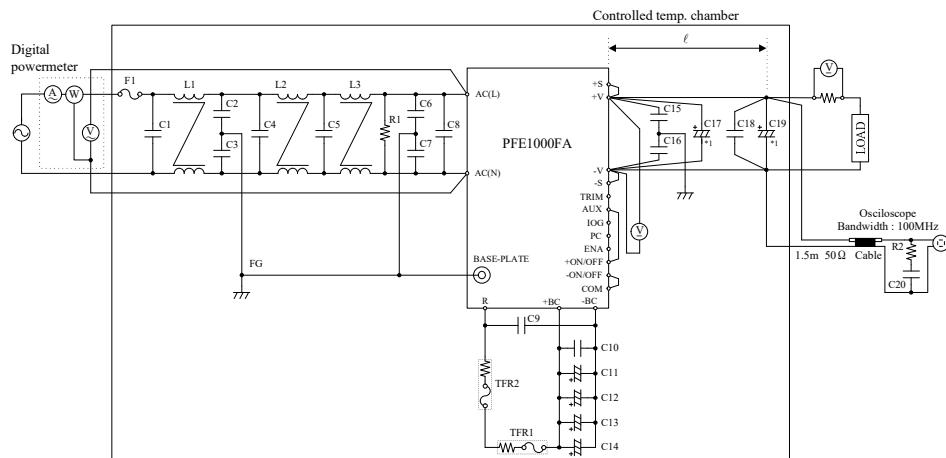
Test results are reference data based on our measurement condition.

## 1. 測定方法 Evaluation Method

### 1-1. 測定回路 Measurement Circuits

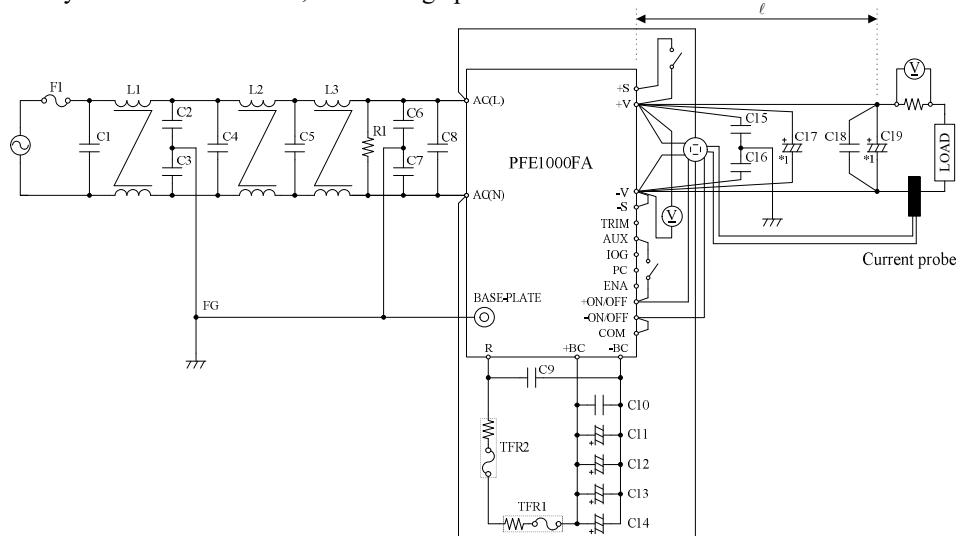
#### (1) 静特性、出力リップル、ノイズ波形、過電流保護機能

Steady state characteristics, output ripple noise waveform and over current protection

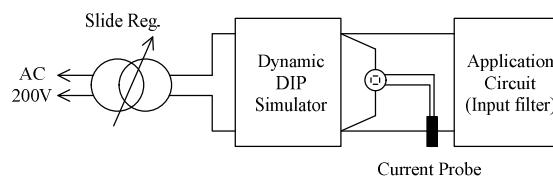


#### (2) 過渡応答、過電圧保護機能、その他

Dynamic characteristics, over voltage protection and other characteristics



#### Inrush current characteristics



C1, C4, C5, C8:

1uF Film Capacitor

C2, C3:

470pF Ceramic Capacitor

C6, C7:

4700pF Ceramic Capacitor

C9, C10:

1uF Film Capacitor

C11, C12, C13, C14: 390uF Electrolytic Capacitor

C15, C16: 0.033uF Film Capacitor

C18: 2.2uF Ceramic Capacitor

C20: 4700pF Ceramic Capacitor

C17, C19:

12V-1000uF Electrolytic Capacitor

28V- 470uF Electrolytic Capacitor

48V- 220uF Electrolytic Capacitor

R1:

0.5W 470kΩ

R2:

50Ω

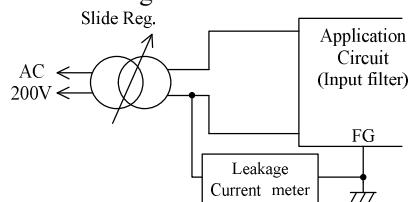
L1, L2, L3: 2mH

$\ell$  : 50mm

TFR1, TFR2: 5.1Ω 139°C

F1: 250VAC, 25A

#### Leakage current characteristics

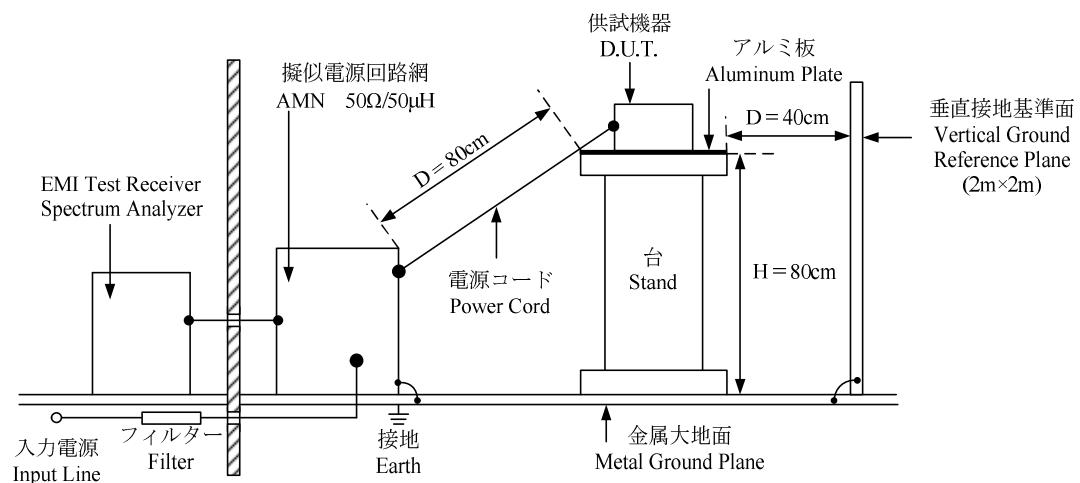


===== Note =====

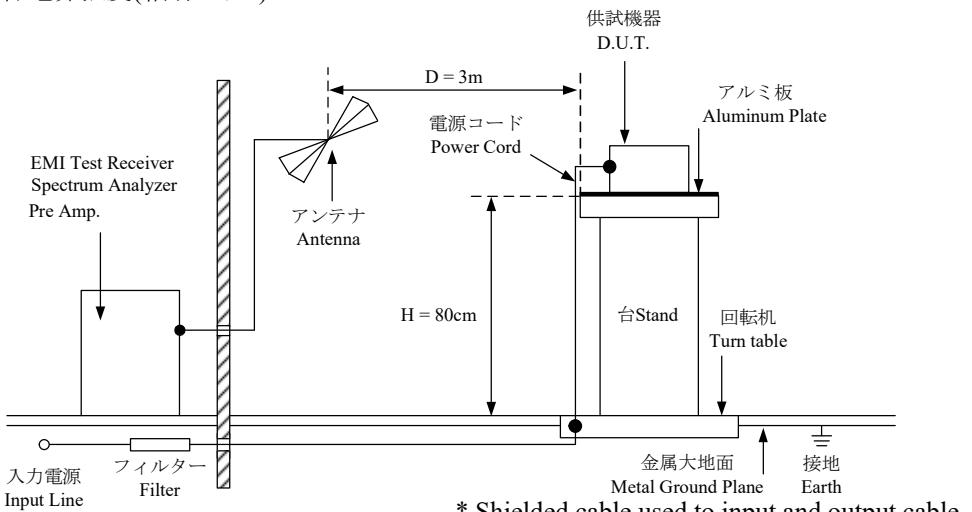
\*1. If the ambient temperature is less than -20°C, use twice of the recommended capacitor above.

## (3) EMI特性 Electro-Magnetic Interference characteristics

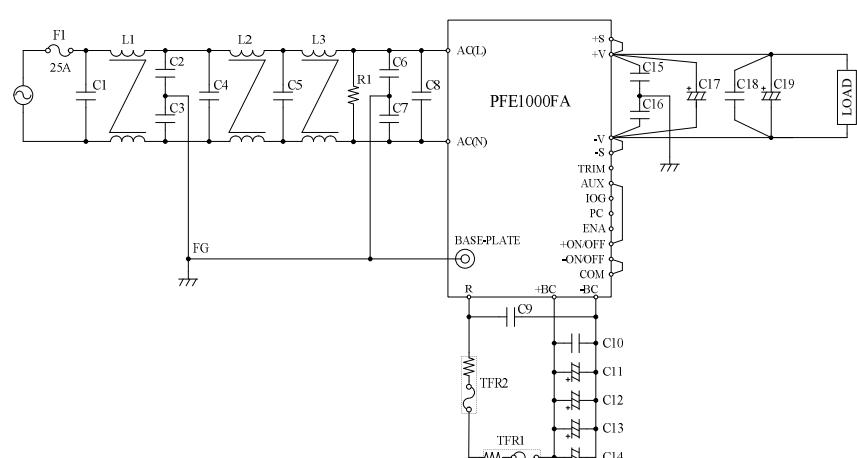
## (a) 雑音端子電圧(帰還ノイズ) Conducted Emission Noise



## (b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



## VCCI class A 対応アプリケーションシステム VCCI class A application system



C1, C4, C5, C8: 1uF Film Capacitor  
 C2, C3: 470pF Ceramic Capacitor  
 C6, C7: 4700pF Ceramic Capacitor  
 C9, C10: 1uF Film Capacitor  
 C11, C12, C13, C14: 390uF Electrolytic Capacitor  
 C15, C16: 0.033uF Film Capacitor  
 C18: 2.2uF Ceramic Capacitor

C17, C19: 12V-1000uF Electrolytic Capacitor  
 28V- 470uF Electrolytic Capacitor  
 48V- 220uF Electrolytic Capacitor  
 R1: 0.5W 470kΩ  
 L1, L2, L3: 2mH  
 TFR1, TFR2: 5.1Ω 139°C  
 F1: 250VAC, 25A

## 1-2. 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL PHOSPHOR OSCILLOSCOPE	YOKOGAWA ELECT.	DLM2504
2	DIGITAL STORAGE OSCILLOSCOPE	IWATSU-LECROY	LT364L
3	DIGITAL POWER METER	YOKOGAWA ELECT.	WT210
4	DATA ACQUISITION / SWITCH UNIT	AGILENT	34970A
5	CURRENT PROBE AMPLIFIER	YOKOGAWA ELECT.	701930
6	CURRENT PROBE	IWATSU-LECROY	AP015
7	SHUNT RESISTER	YOKOGAWA ELECT.	2215
8	CONTROLLED TEMP. CHAMBER	ESPEC CORP.	SU-261
9	HARMONIC / FLICKER ANALYZER	KIKUSUI	KHA1000
10	EMI TEST RECEIVER / SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESCI
11	PRE AMP	SONOMA	310N
12	AC POWER SUPPLY	NF	ES10000S
13	AMN	SCHWARZBECK	NNLK8121
14	ANTENNA(BICONICAL ANTENNA)	SCHWARZBECK	CBL6111D
15	DYNAMIC DUMMY LOAD	TAKASAGO	FK-1000L
16	AC POWER SUPPLY	TAKASAGO	AA2000XG
17	INRUSH CURRENT METER	TAKAMISAWA	PSA-210
18	SLIDE REGULATOR	MATSUNAGA	SD-2650
19	A.C. LEAKAGE CURRENT TESTER	HIOKI	3156
20	SINGLE-PHASE MASTER	NF	4420
21	REFERENCE CURRENT METER	NF	4150

## 2. 特性データ Characteristics

### 2-1. 静特性 Steady state characteristics

(1) 入力・負荷・温度変動 Regulation - line and load, Temperature drift

12V
-----

#### 1. Regulation - line and load

Condition Tbp : 25°C

Iout \ Vin	85VAC	100VAC	200VAC	265VAC	Line regulation	
0%	12.105V	12.105V	12.106V	12.105V	1mV	0.008%
50%	12.104V	12.104V	12.104V	12.104V	0mV	0.000%
100%	12.103V	12.103V	12.103V	12.102V	1mV	0.008%
Load regulation	2mV	2mV	3mV	3mV		
	0.017%	0.017%	0.025%	0.025%		

#### 2. Temperature drift

Conditions Vin=100VAC

Iout=100%

Tbp	-40°C	+25°C	+100°C	Temperature stability	
Vout	12.082V	12.103V	12.034V	69mV	0.575%

28V
-----

#### 1. Regulation - line and load

Condition Tbp : 25°C

Iout \ Vin	85VAC	100VAC	200VAC	265VAC	Line regulation	
0%	28.040V	28.040V	28.040V	28.040V	0mV	0.000%
50%	28.040V	28.040V	28.040V	28.040V	0mV	0.000%
100%	28.040V	28.040V	28.040V	28.040V	0mV	0.000%
Load regulation	0mV	0mV	0mV	0mV		
	0.000%	0.000%	0.000%	0.000%		

#### 2. Temperature drift

Conditions Vin=100VAC

Iout=100%

Tbp	-40°C	+25°C	+85°C	Temperature stability	
Vout	27.967V	28.040V	27.900V	140mV	0.499%

48V
-----

#### 1. Regulation - line and load

Condition Tbp : 25°C

Iout \ Vin	85VAC	100VAC	200VAC	265VAC	Line regulation	
0%	47.935V	47.935V	47.934V	47.934V	1mV	0.002%
50%	47.935V	47.935V	47.934V	47.934V	1mV	0.002%
100%	47.935V	47.935V	47.934V	47.934V	1mV	0.002%
Load regulation	0mV	0mV	0mV	0mV		
	0.000%	0.000%	0.000%	0.000%		

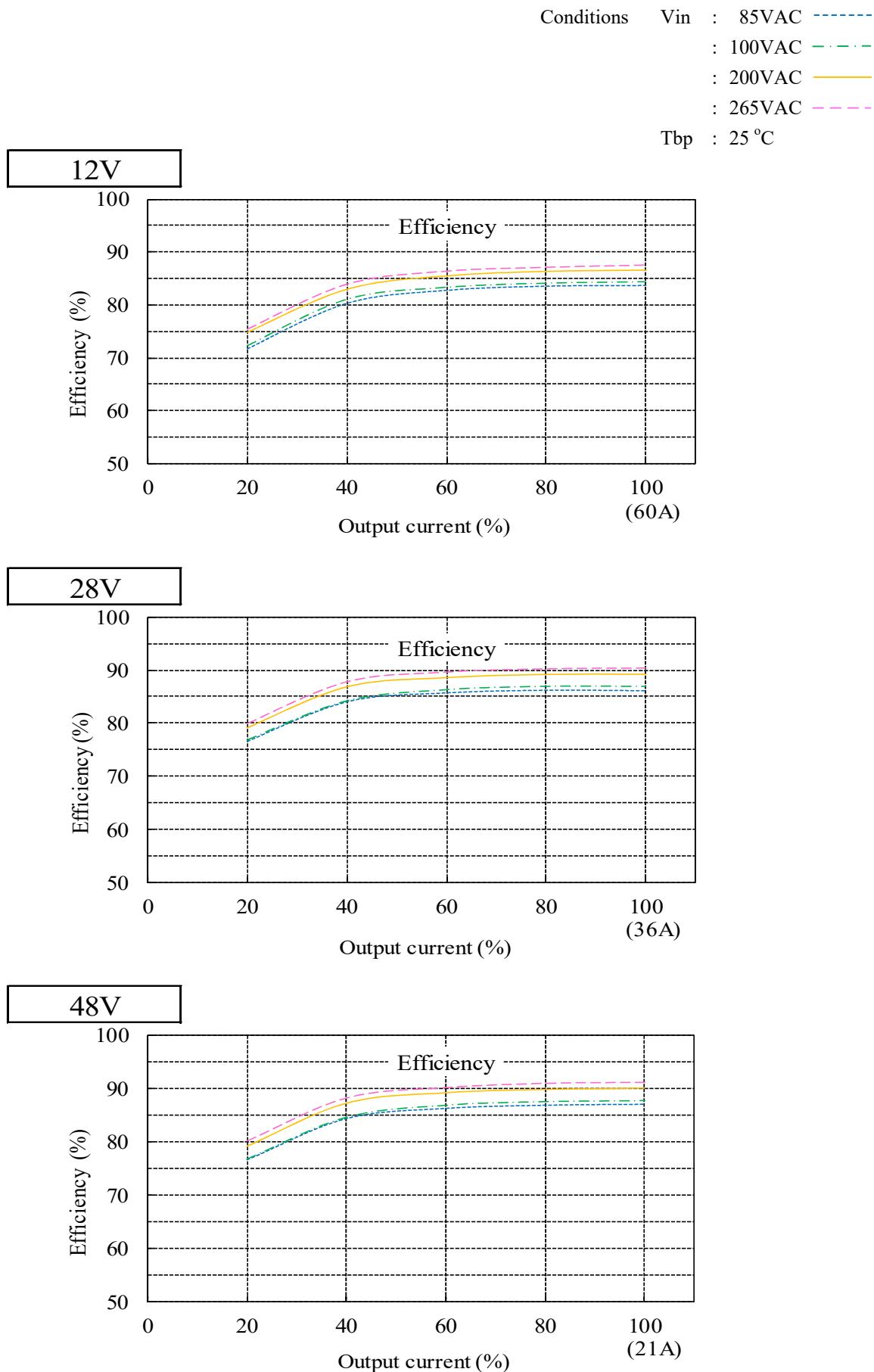
#### 2. Temperature drift

Conditions Vin=100VAC

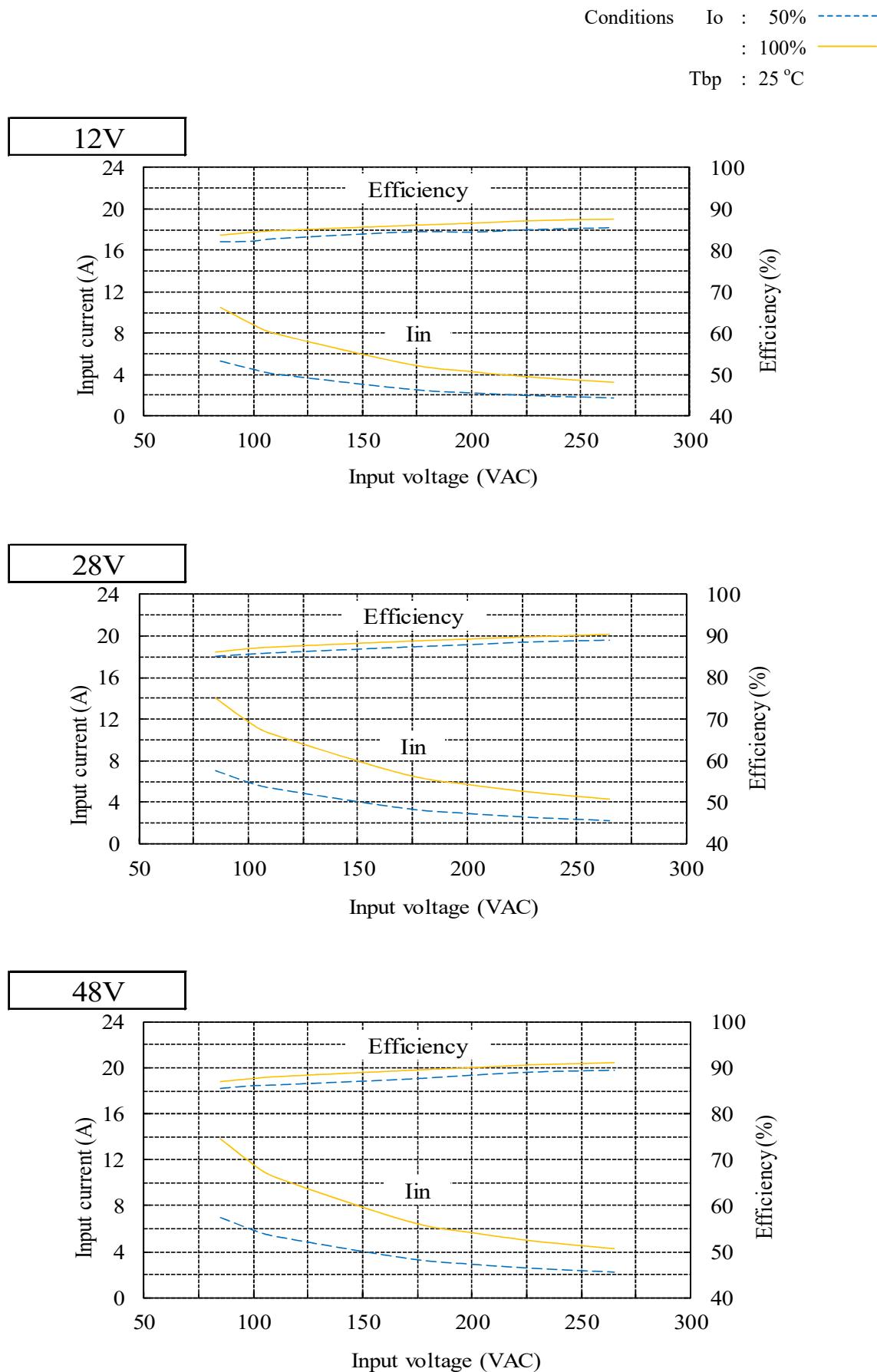
Iout=100%

Tbp	-40°C	+25°C	+85°C	Temperature stability	
Vout	47.920V	48.134V	47.614V	520mV	1.084%

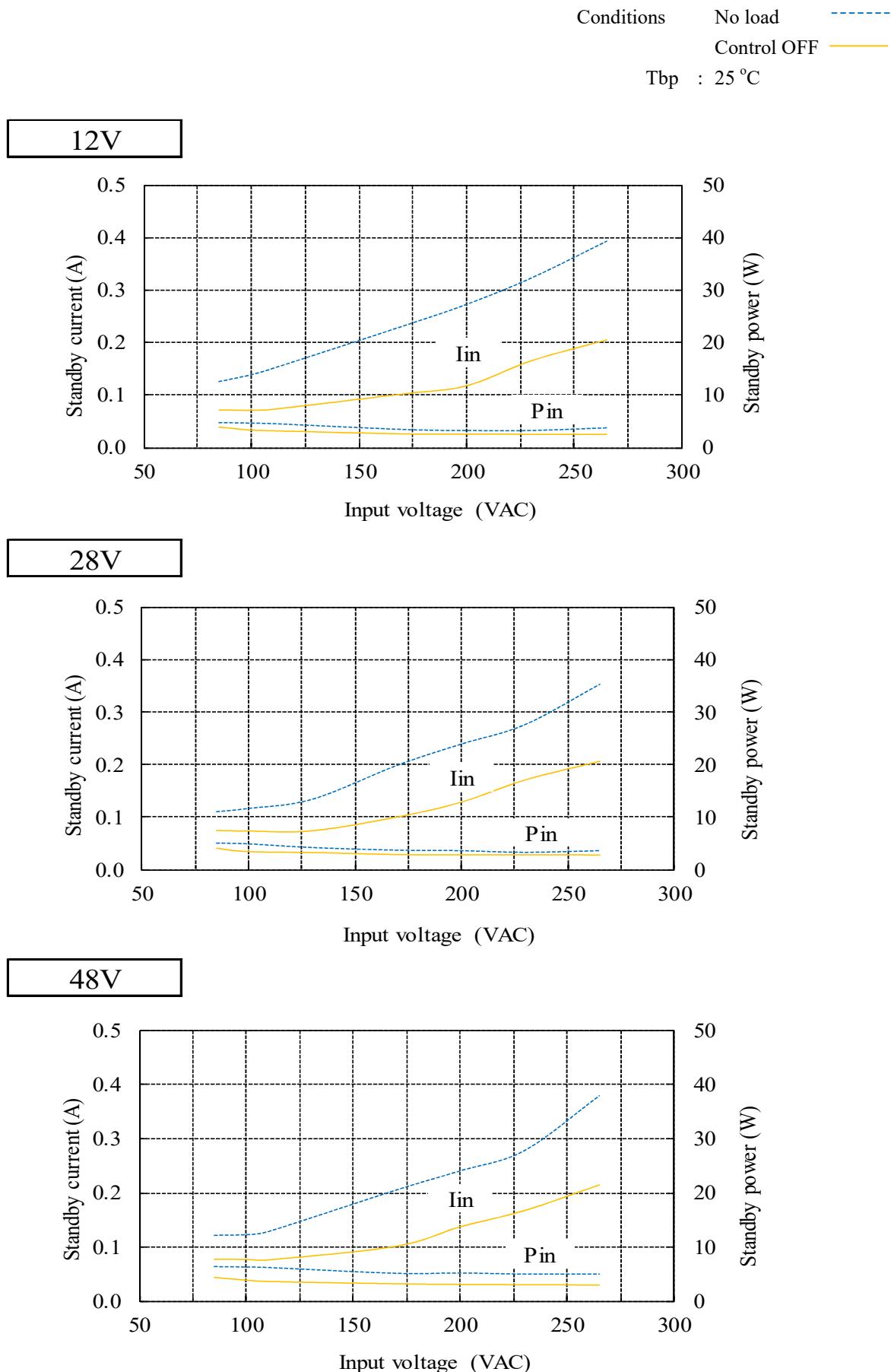
(2) 効率 対 出力電流 Efficiency vs. Output current



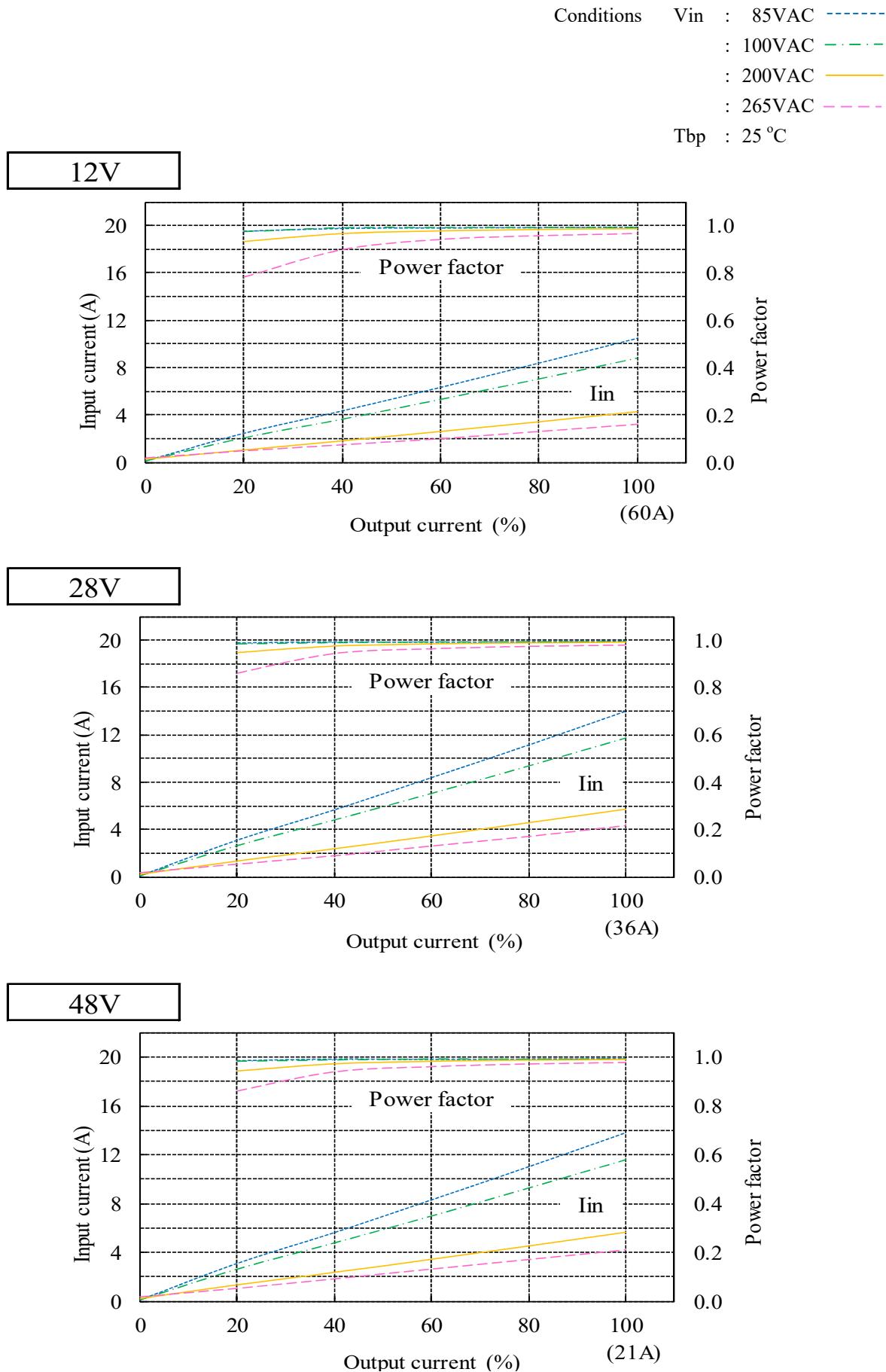
## (3) 入力電流・効率 対 入力電圧 Input current and Efficiency vs. Input voltage



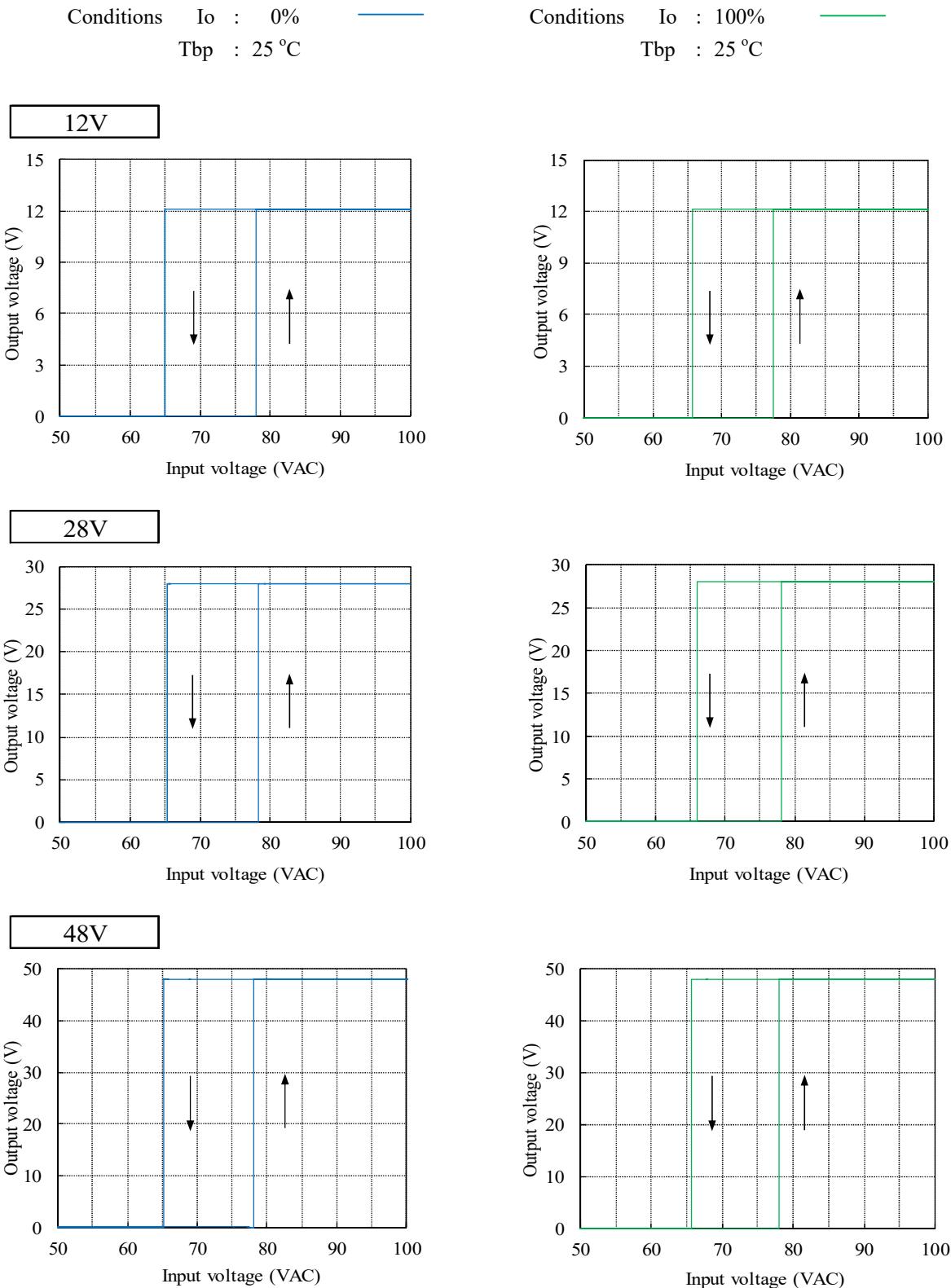
## (4) 待機電流・電力特性 Standby current and power characteristics



## (5) 入力電流・力率 対 出力電流 Input current and Power factor vs. Output current

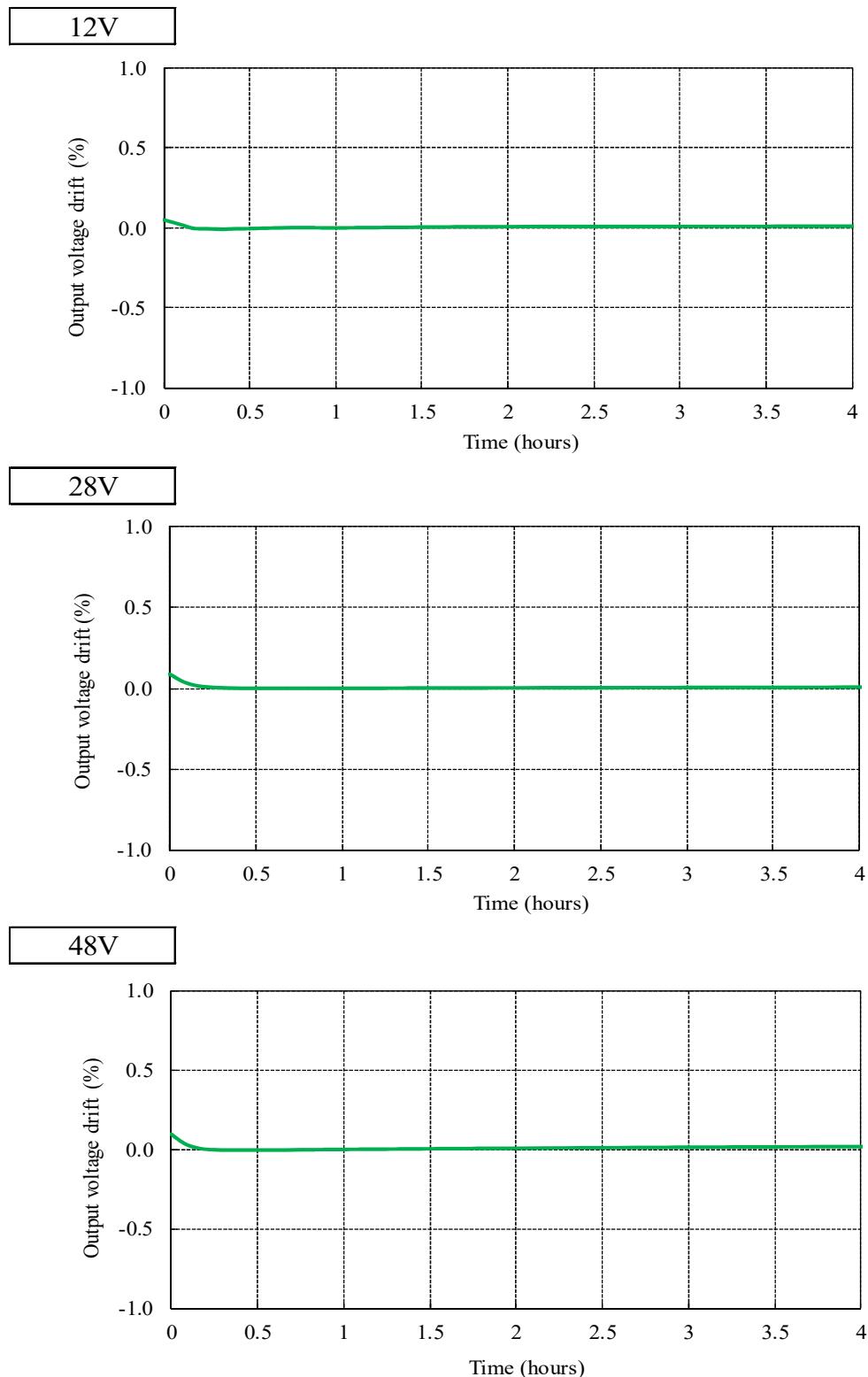


## (6) 起動・停止電圧特性 Start and Stop voltage characteristics



## 2-2. 通電ドリフト特性 Warm up voltage drift characteristics

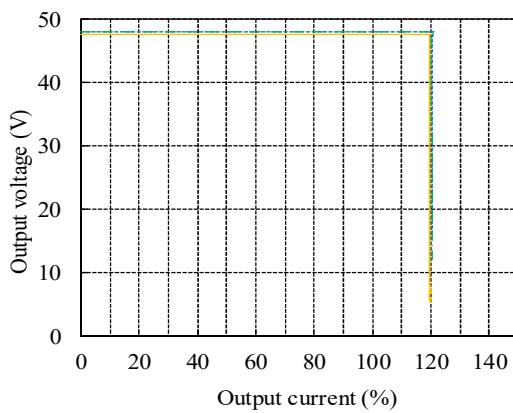
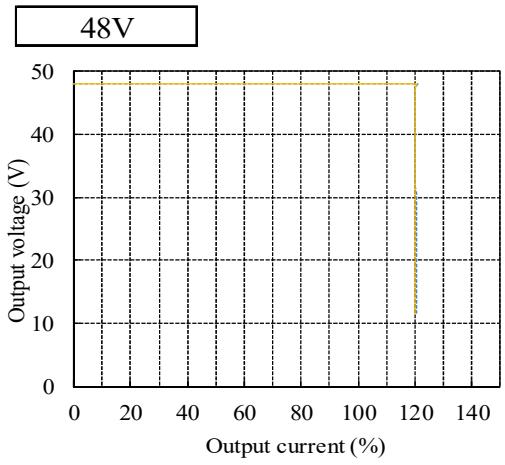
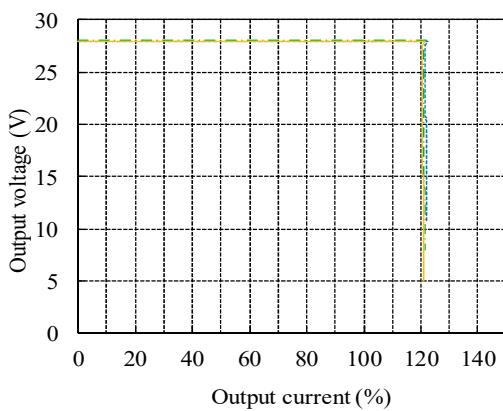
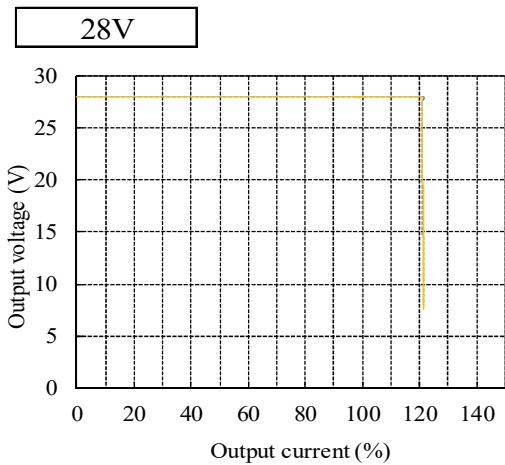
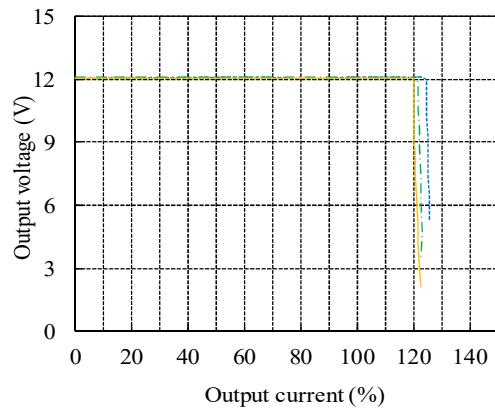
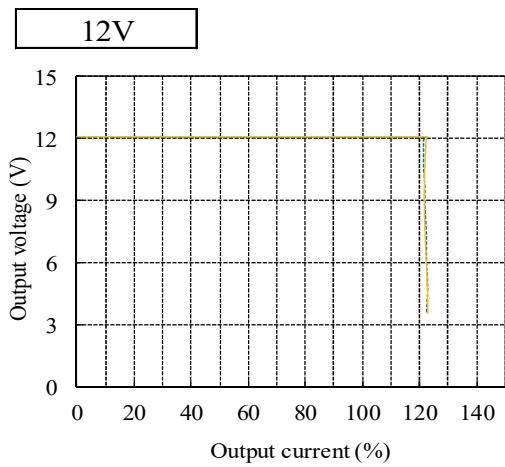
Conditions      Vin : 100VAC  
                  Io : 100%  
                  Tbp : 25 °C



2-3. 過電流保護特性 Over current protection (OCP) characteristics

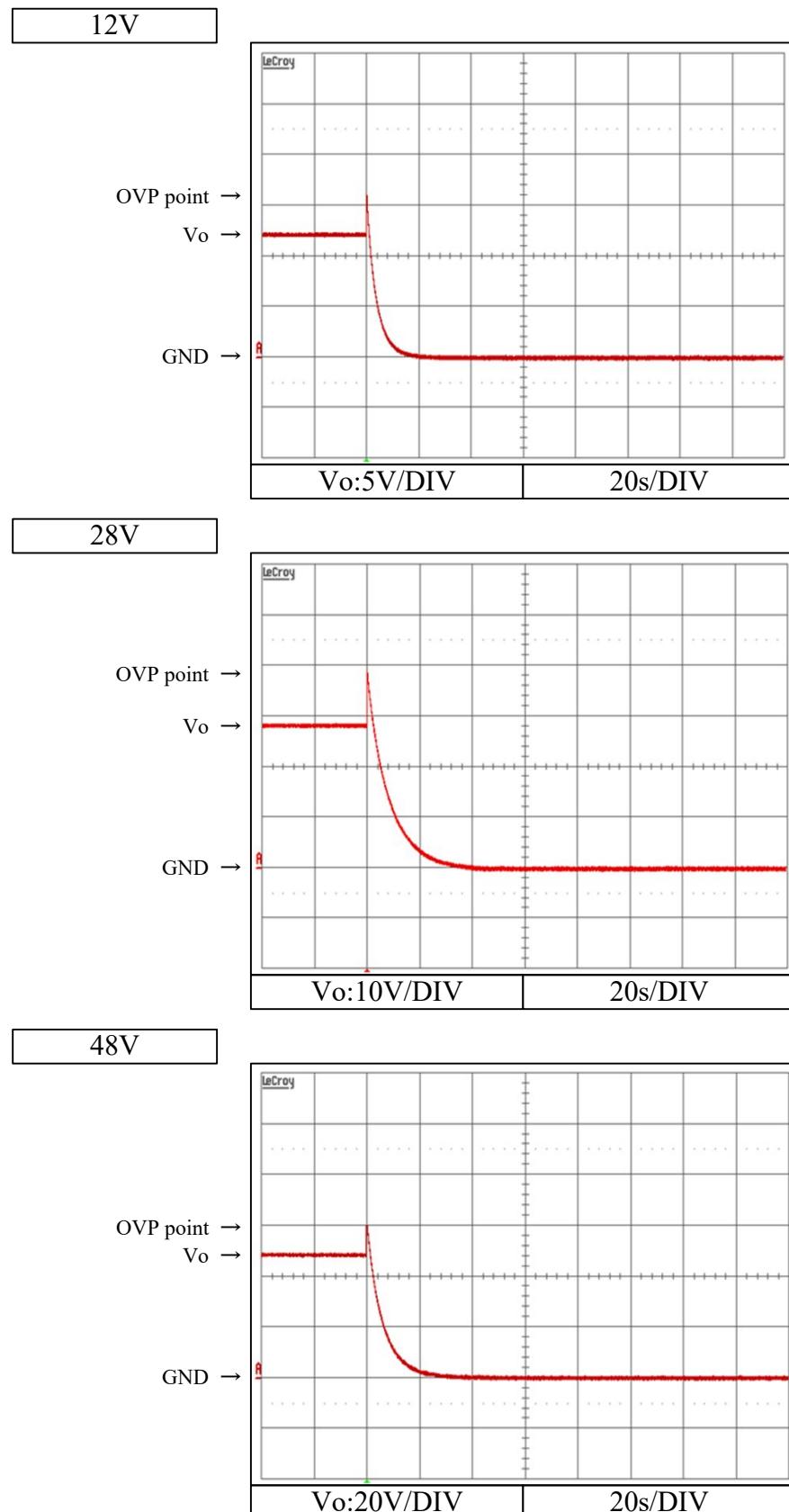
Conditions      Vin : 100VAC -----  
 200VAC ———  
 Tbp : 25 °C

Conditions      Vin : 100VAC  
 Tbp : -40°C -----  
 25 °C - - - - -  
 100°C ———



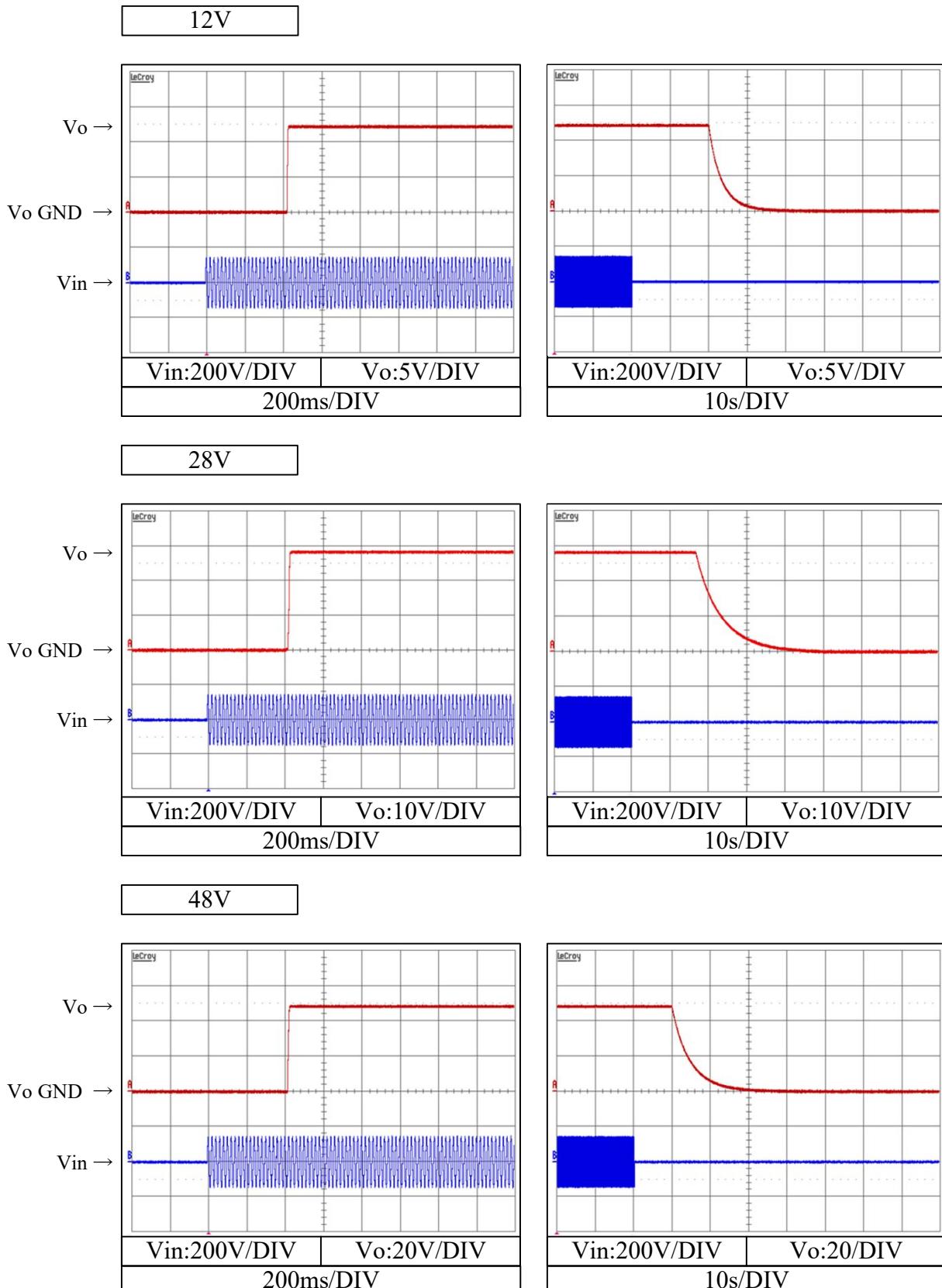
## 2-4. 過電壓保護特性 Over voltage protection (OVP) characteristics

Conditions      Vin : 100VAC  
                  Io : 0%  
                  Tbp : 25 °C



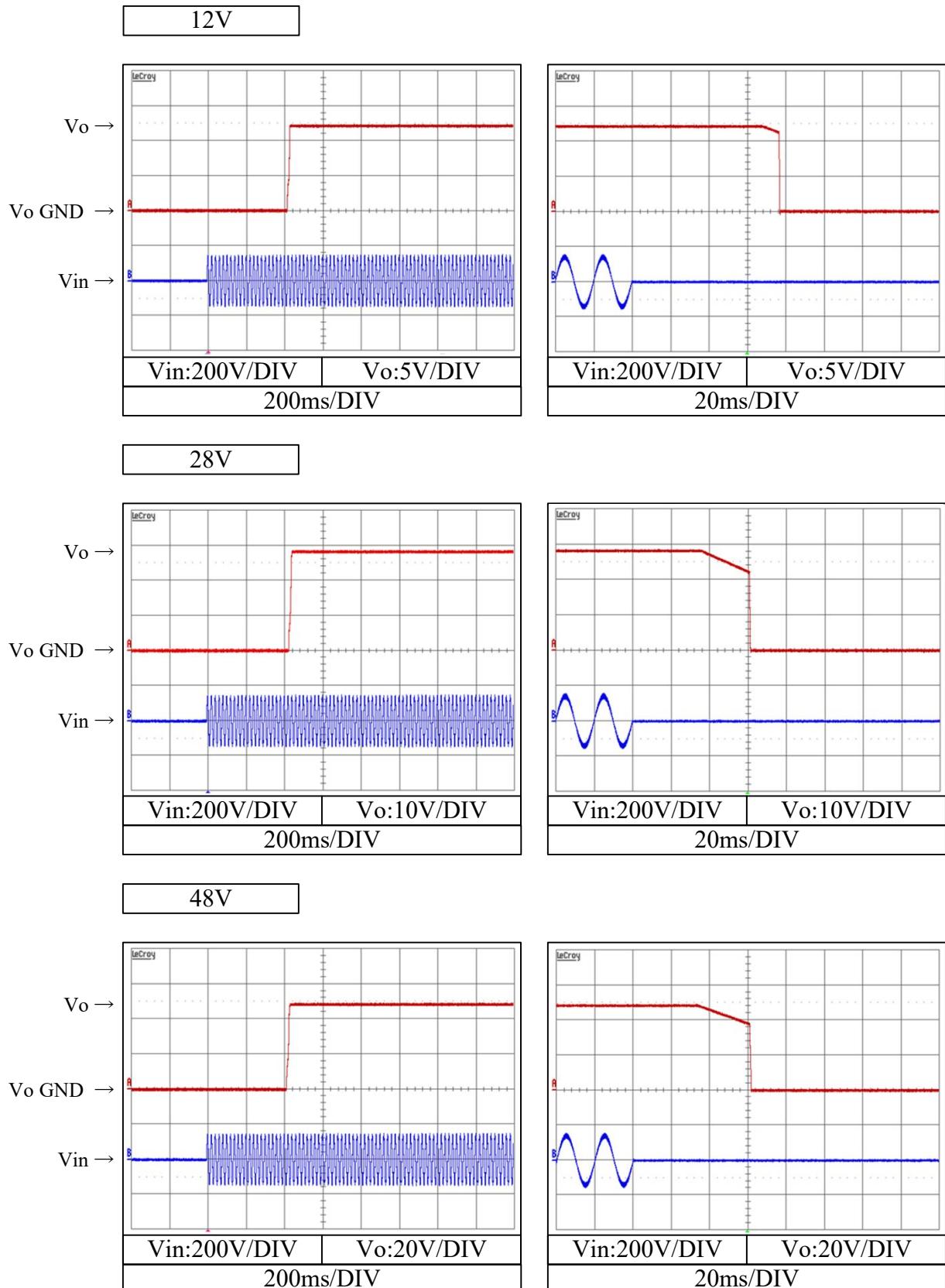
2-5. 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

Conditions      Vin : 100VAC  
 Io : 0%  
 Tbp : 25 °C



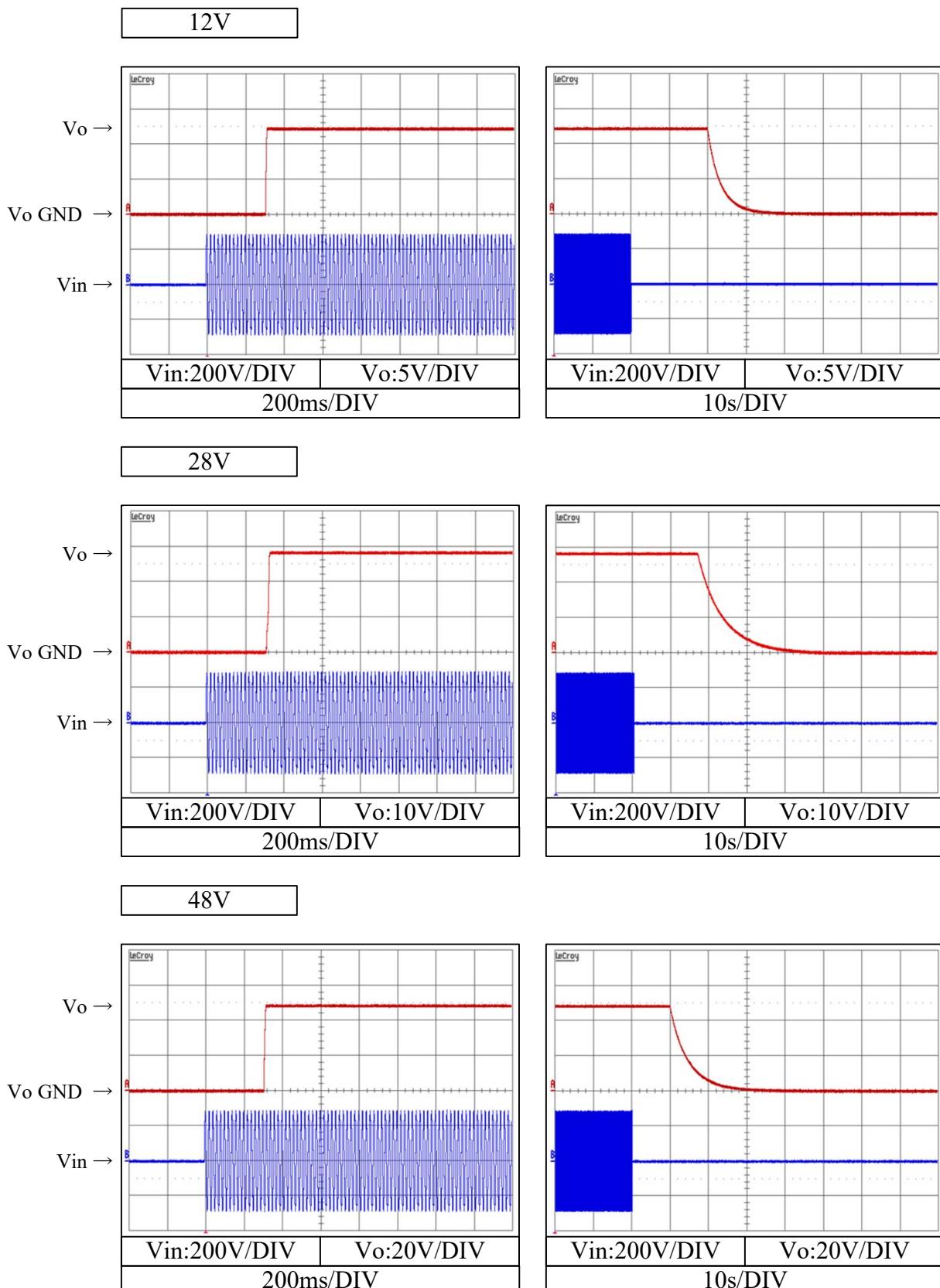
2-5. 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

Conditions      Vin : 100VAC  
 Io : 100%  
 Tbp : 25 °C



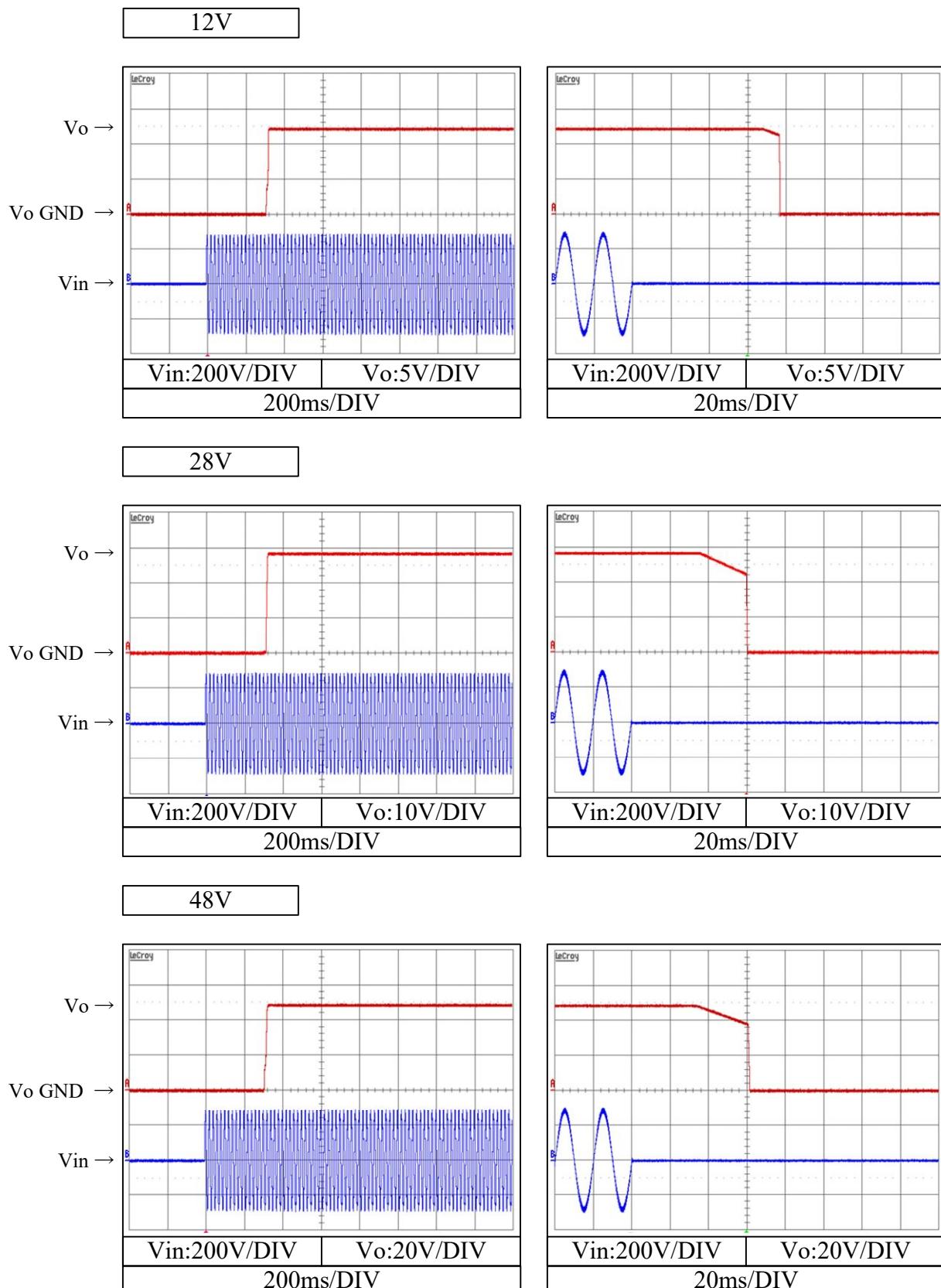
2-5. 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

Conditions      Vin : 200VAC  
 Io : 0%  
 Tbp : 25 °C



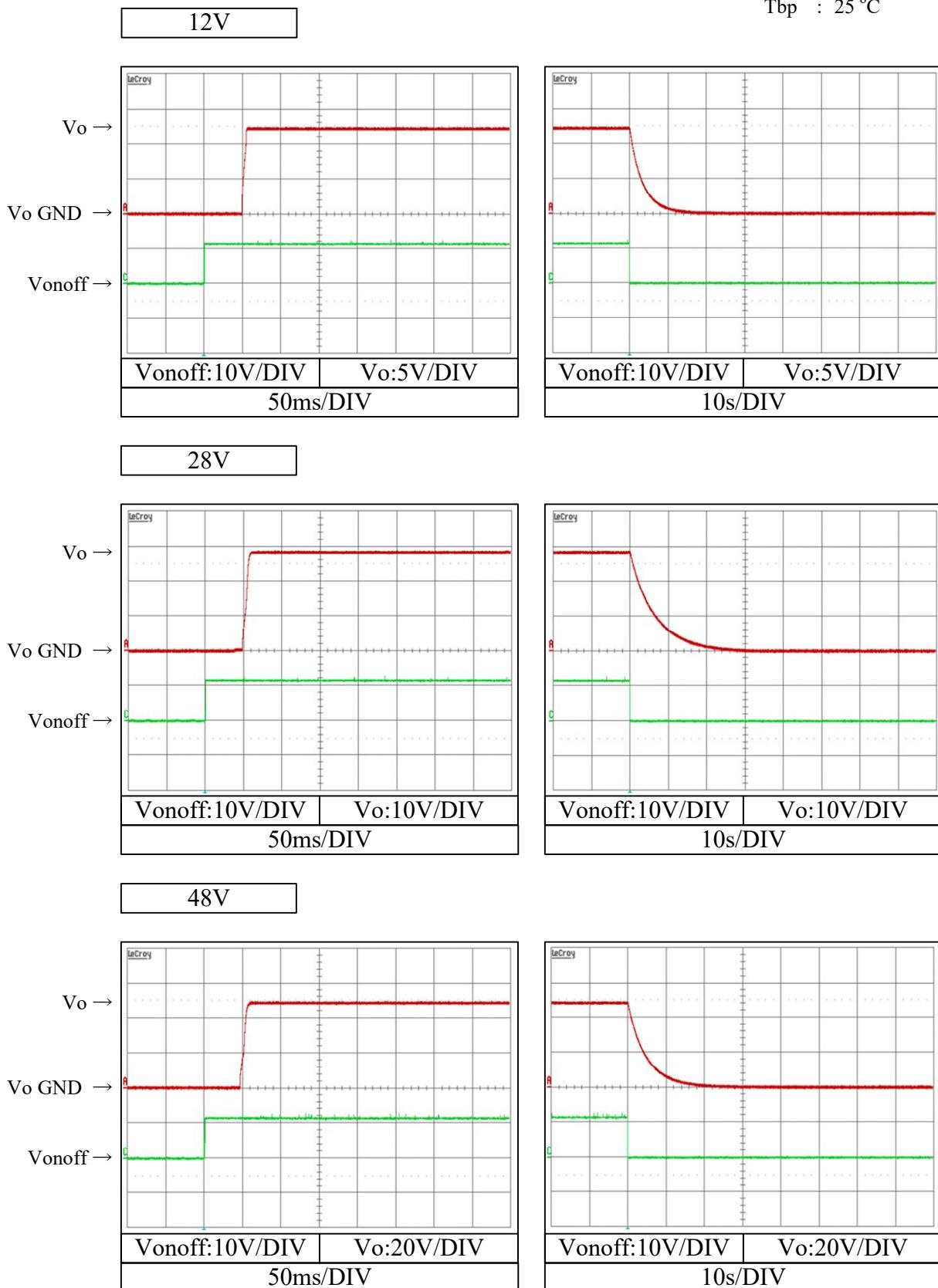
2-5. 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

Conditions      Vin : 200VAC  
 Io : 100%  
 Tbp : 25 °C



- 2-6. 出力立ち上がり、立ち下り特性(ON/OFFコントロール時)  
Output rise and fall characteristics with ON/OFF CONTROL

Conditions      Vin : 100VAC  
                  Io : 0%  
                  Tbp : 25 °C

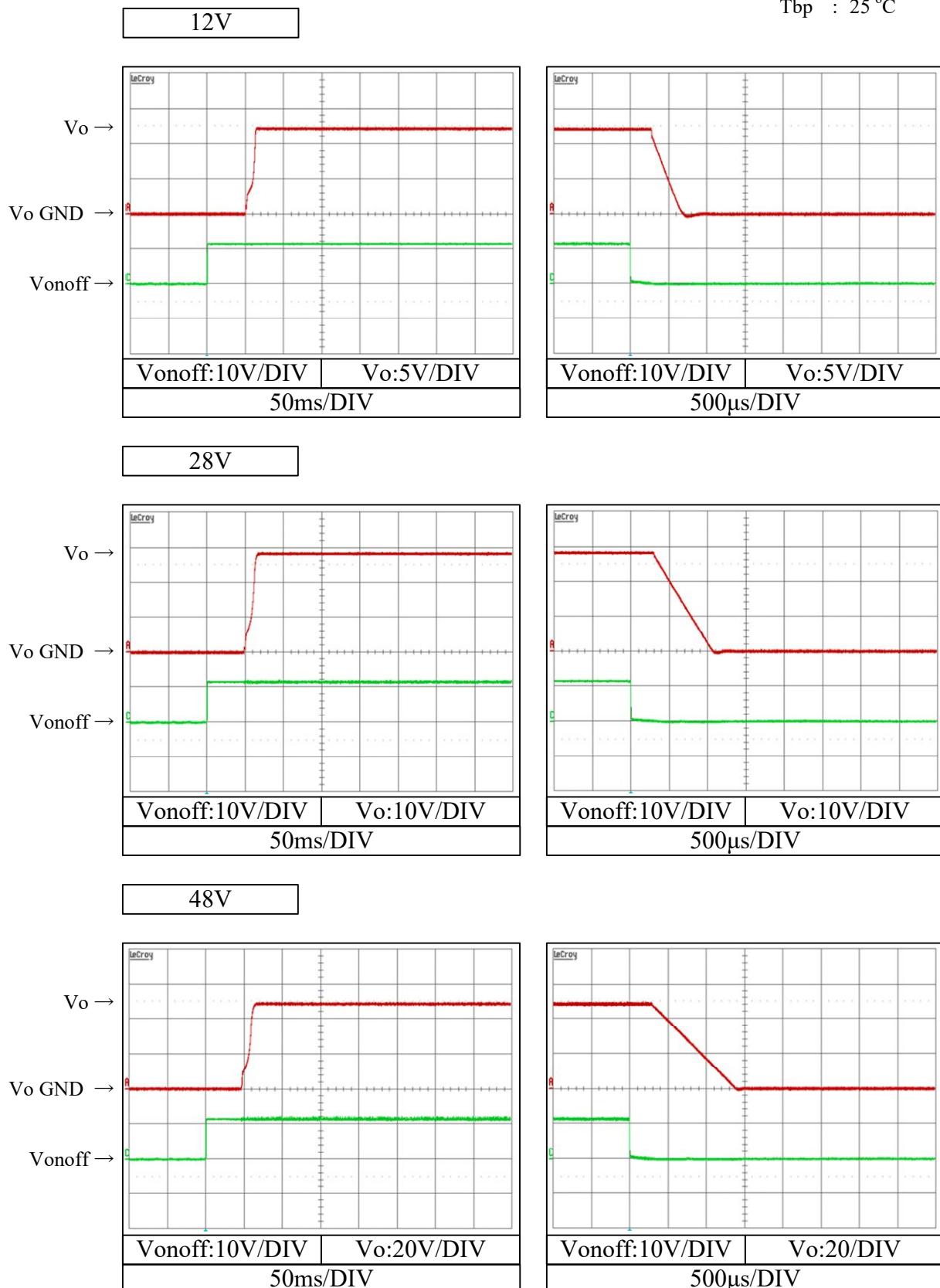


Note : 200VAC is same as characteristics of 100VAC

2-6. 出力立ち上がり、立ち下り特性(ON/OFFコントロール時)

Output rise and fall characteristics with ON/OFF CONTROL

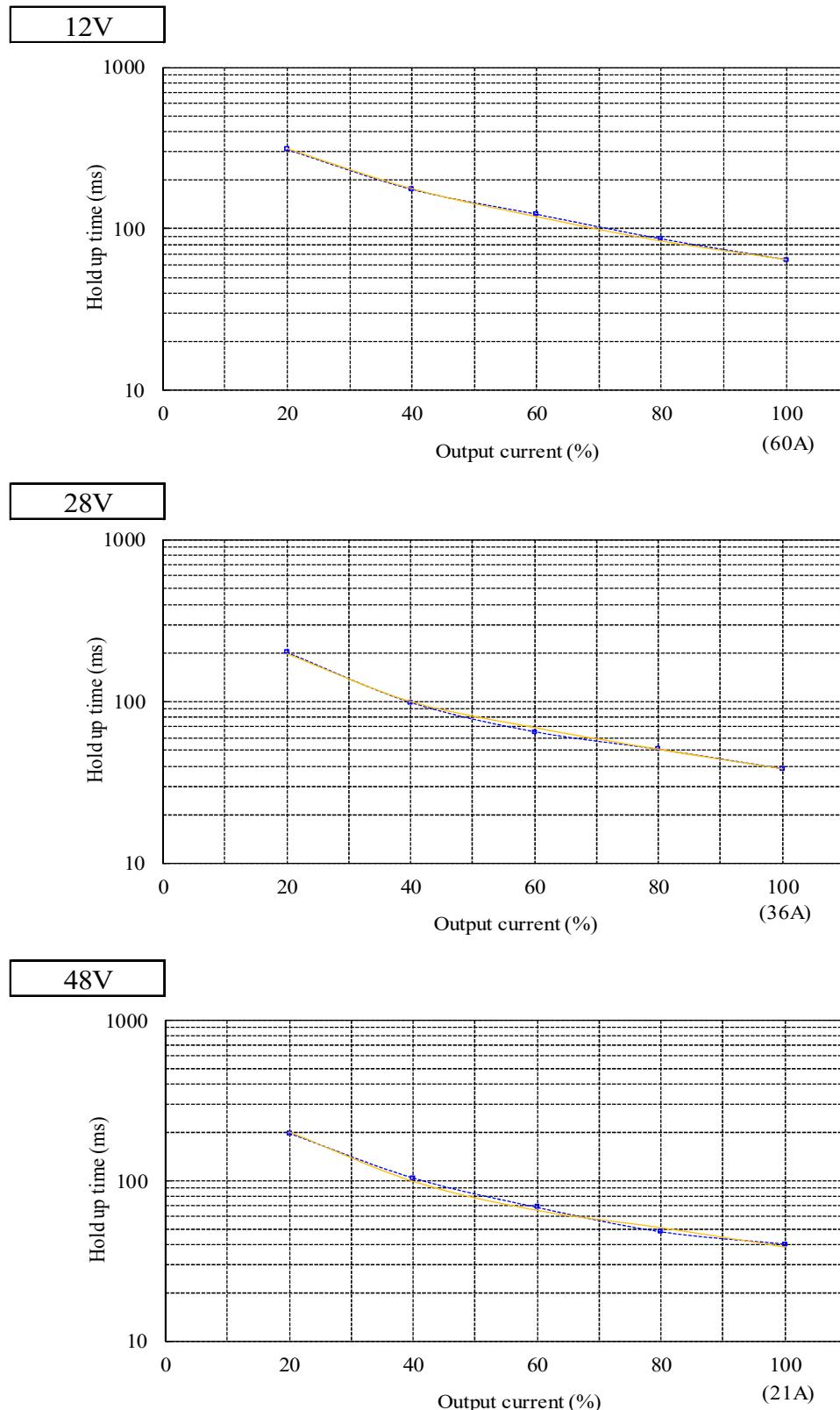
Conditions      Vin : 100VAC  
 Io : 100%  
 Tbp : 25 °C



Note : 200VAC is same as characteristics of 100VAC

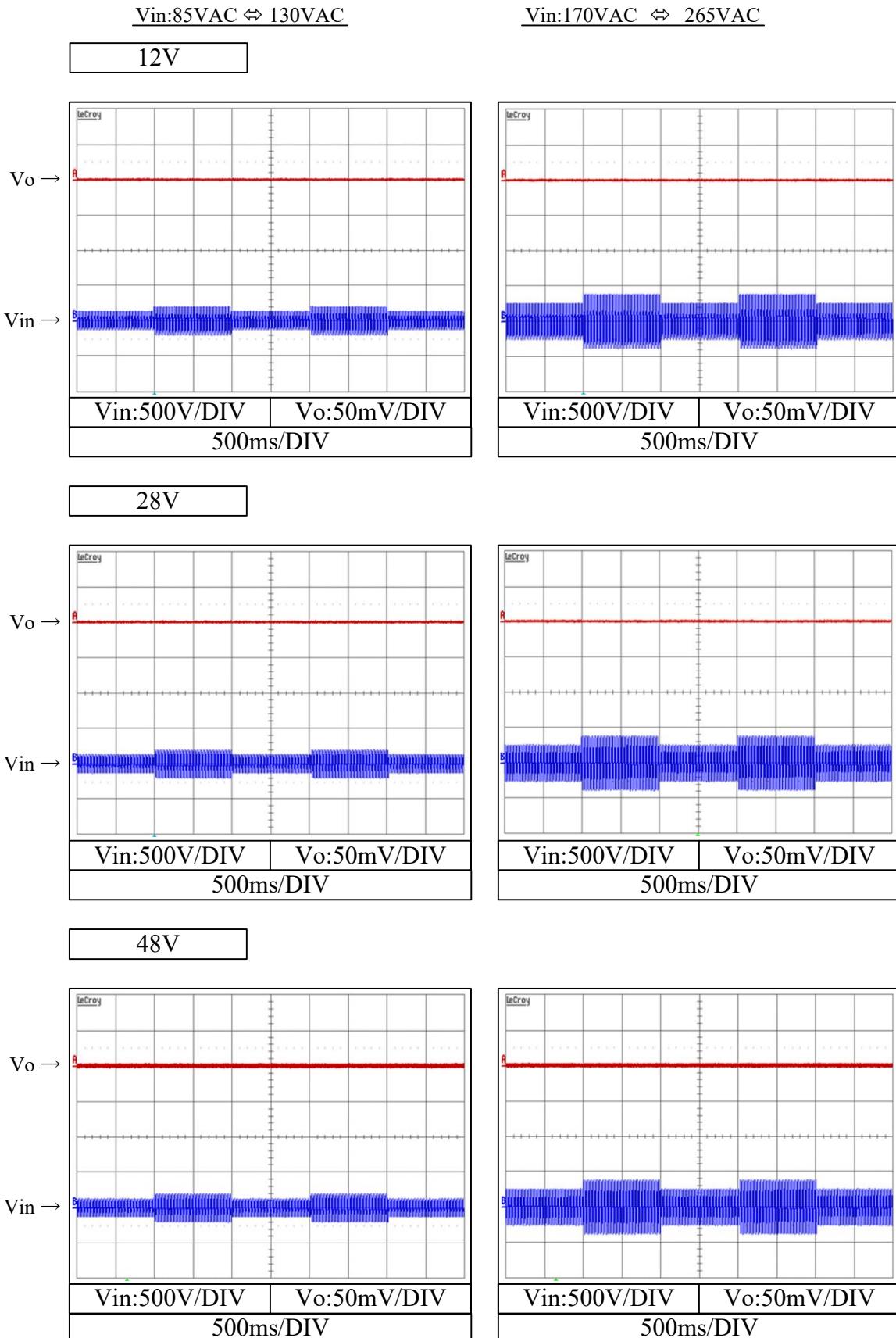
## 2-7. 出力電圧保持時間特性 Hold up time characteristics

Conditions      Vin : 100VAC -----  
                  200VAC ————  
                  Tbp : 25 °C



## 2-8. 過渡応答(入力急変)特性 Dynamic line response characteristics

Conditions      Io : 100%  
 Tbp : 25 °C

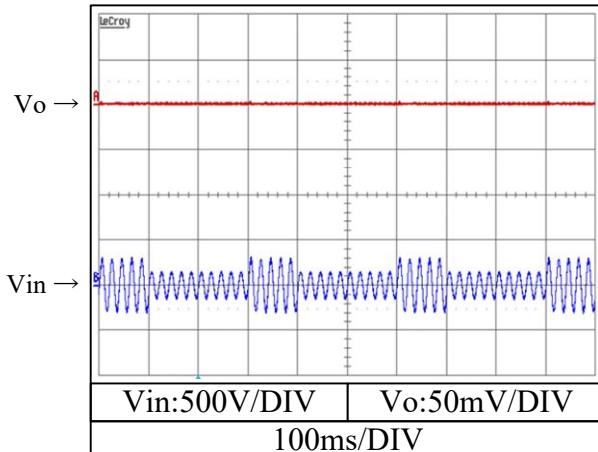


## 2-8. 過渡応答(入力急変)特性 Dynamic line response characteristics

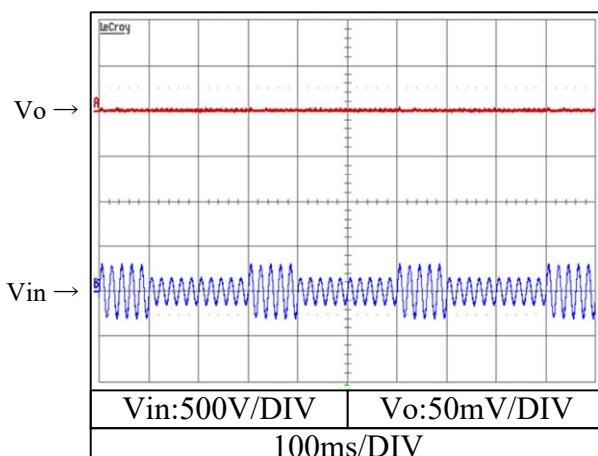
Conditions  
Io : 100%  
Tbp : 25 °C

Vin:100VAC ↔ 200VAC

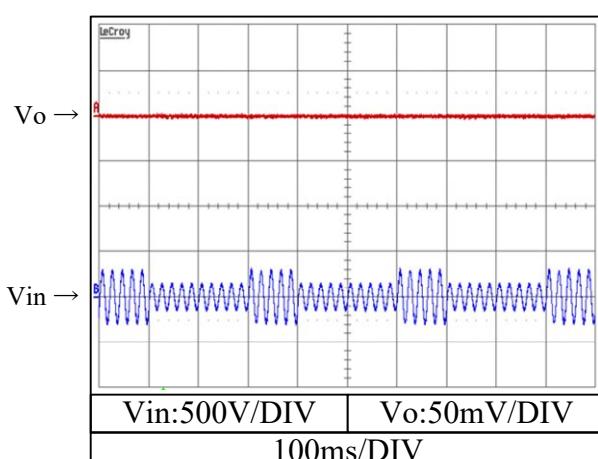
12V



28V



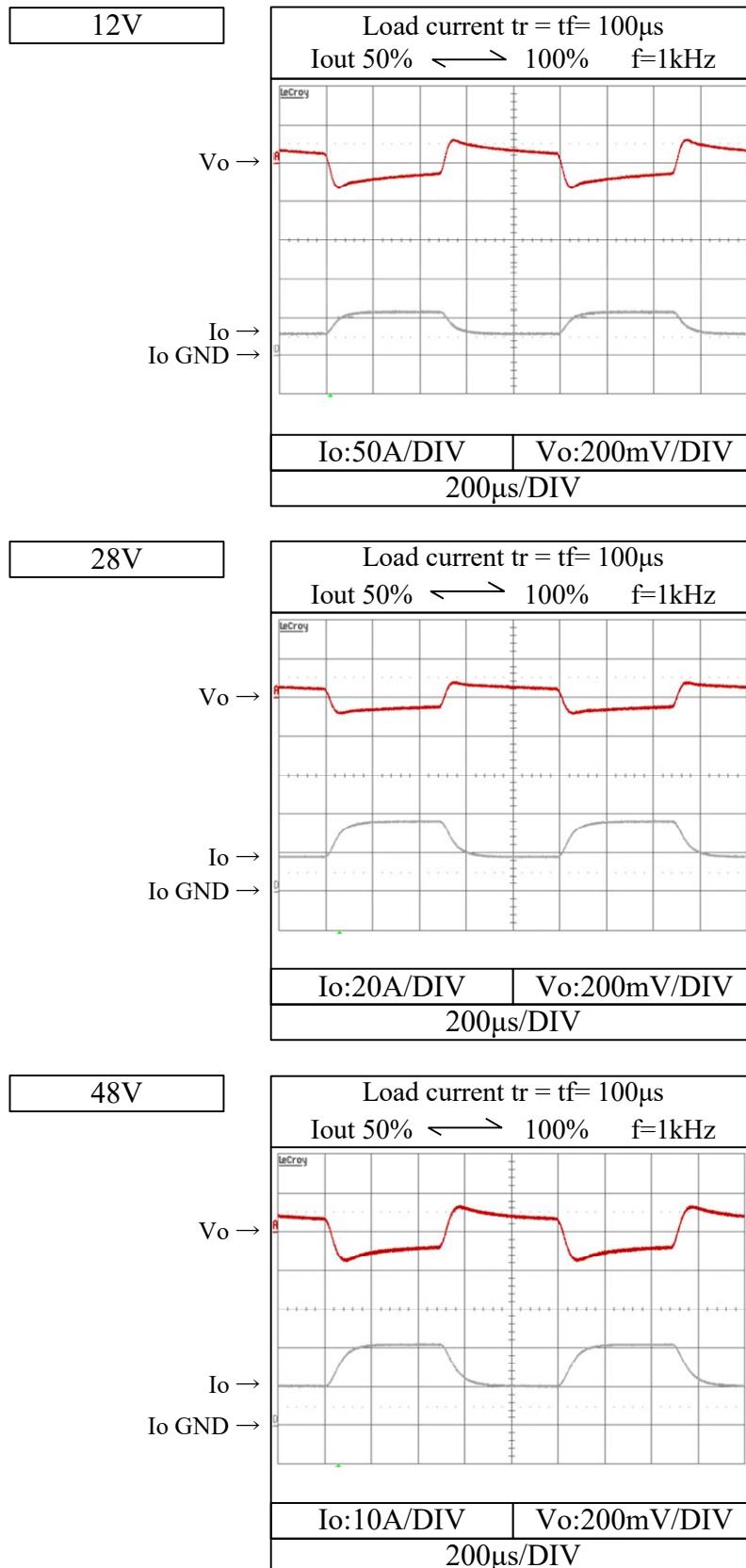
48V



Note : This test follows SEMI F47-0200

## 2-9. 過渡応答(負荷急変)特性 Dynamic load response characteristics

Conditions      Vin : 100VAC  
 Tbp : 25 °C



## 2-10. 入力電圧瞬停特性 Response to brownout characteristics

Conditions Io : 100%

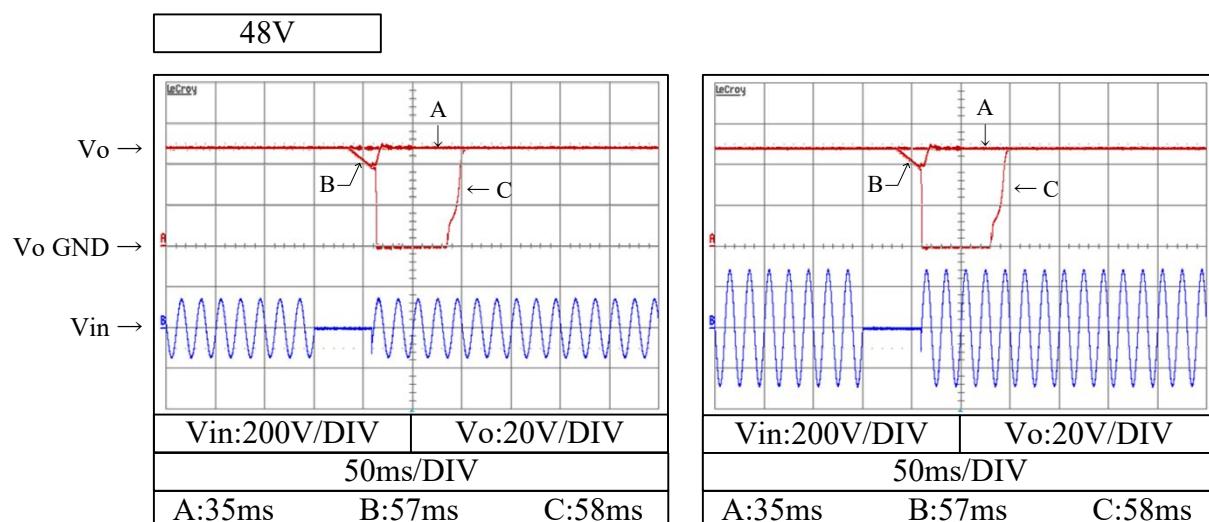
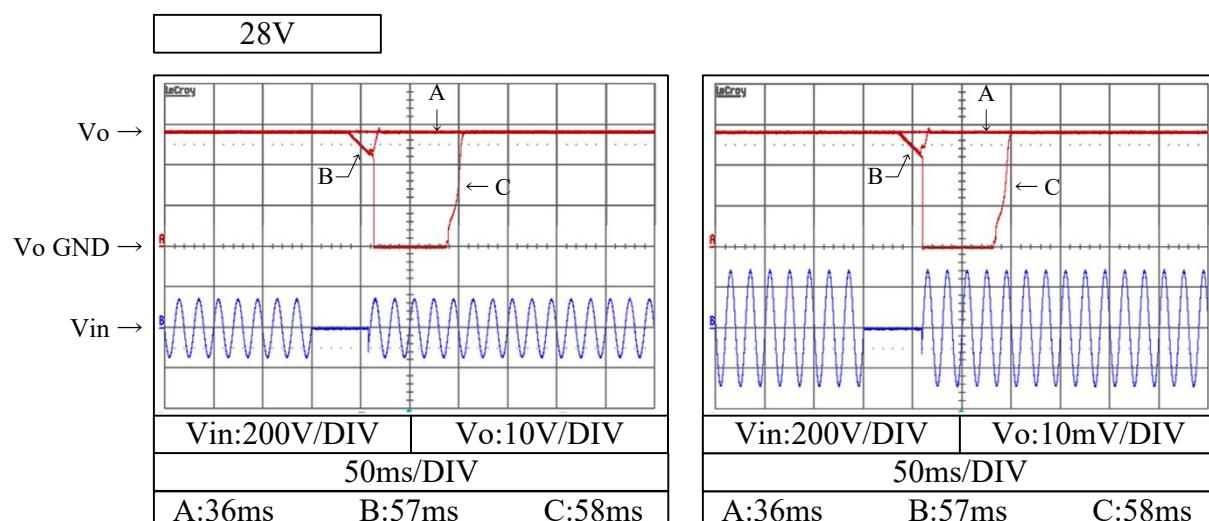
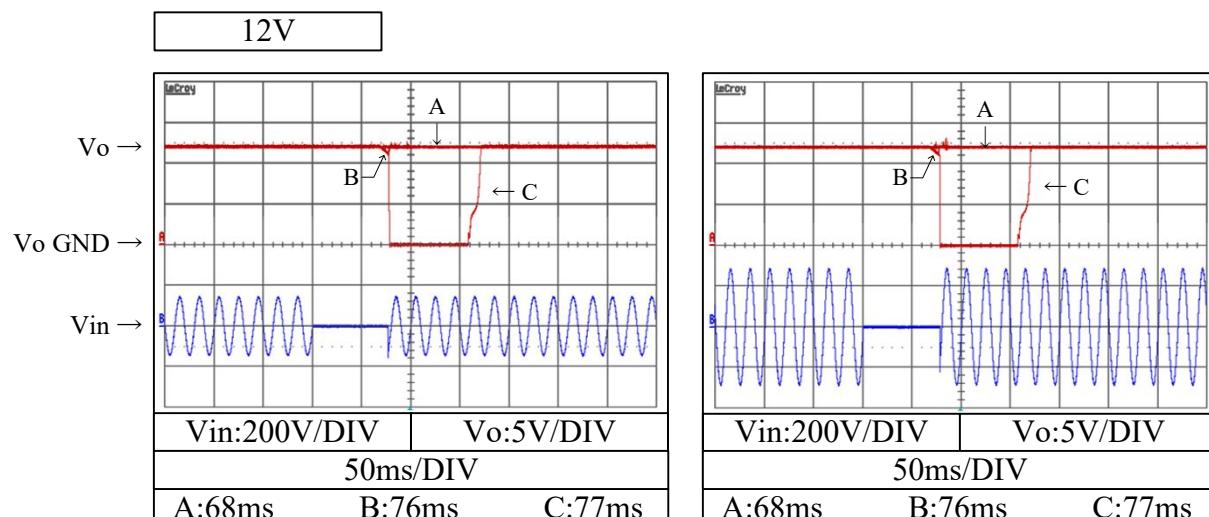
Tbp : 25 °C

## 瞬停時間 Interruption time

A: 出力電圧が低下なし Output voltage does not drop.

B: 出力電圧の低下が0Vまでいかない output voltage drop down not reaching 0V.

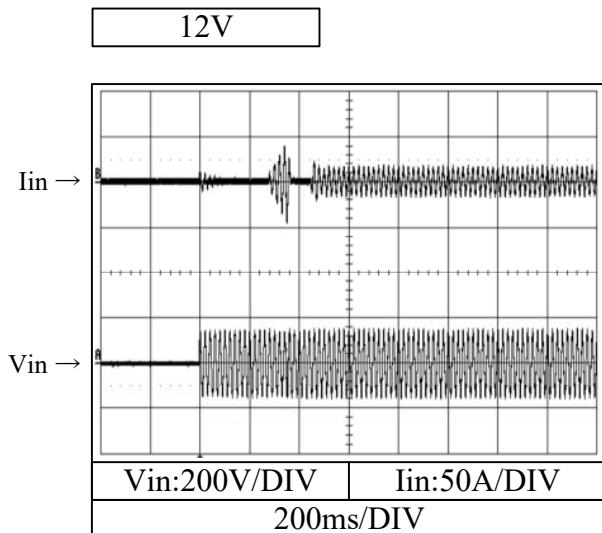
C: 出力電圧が0Vまで低下 Output voltage drops until 0V.

Vin:100VACVin:200VAC

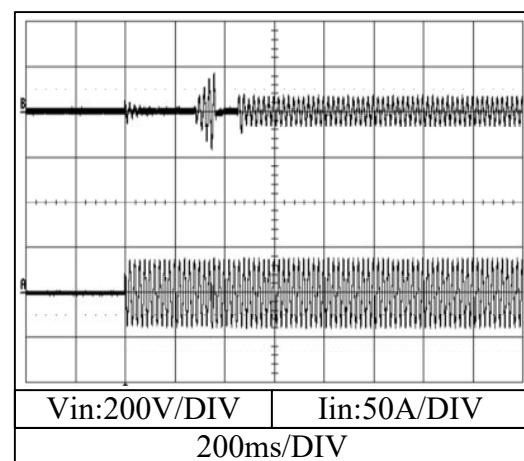
## 2-11. 入力サージ電流(突入電流)特性 Inrush current characteristics

Conditions      Vin : 100VAC  
                  Io : 100%  
                  Tbp : 25 °C

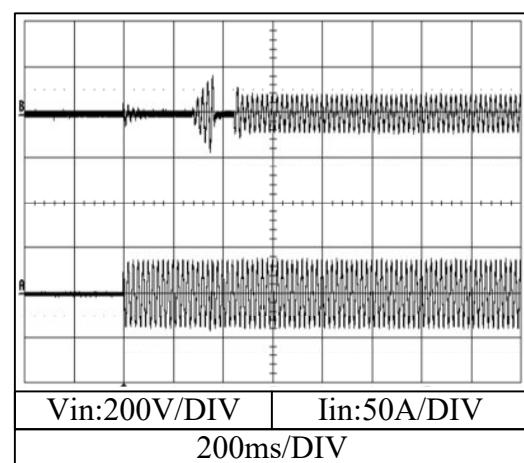
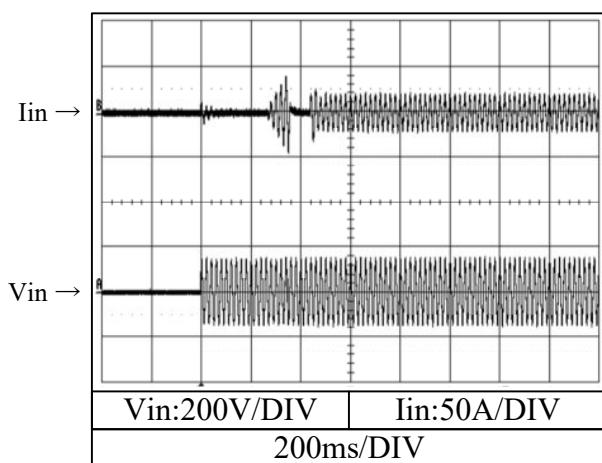
Switch on phase angle  
of input AC voltage  $\phi = 0^\circ$



Switch on phase angle  
of input AC voltage  $\phi = 90^\circ$



48V

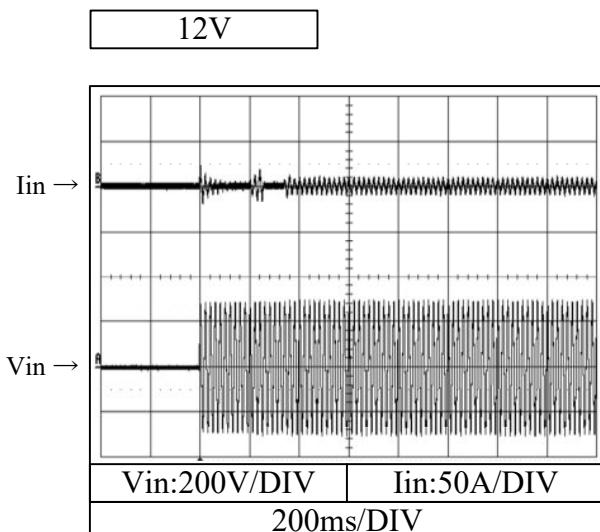


Note : 28V is same as characteristics of 48V

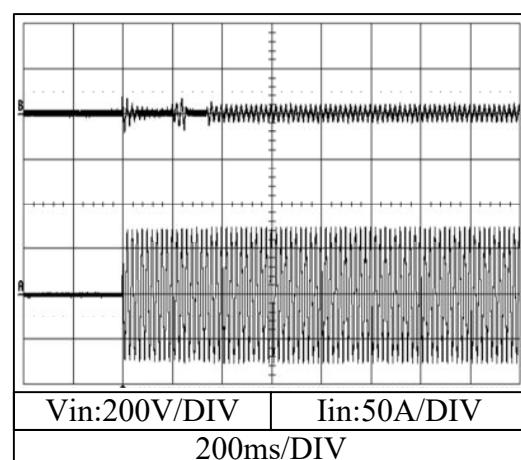
## 2-11. 入力サージ電流(突入電流)特性 Inrush current characteristics

Conditions      Vin : 200VAC  
                  Io : 100%  
                  Tbp : 25 °C

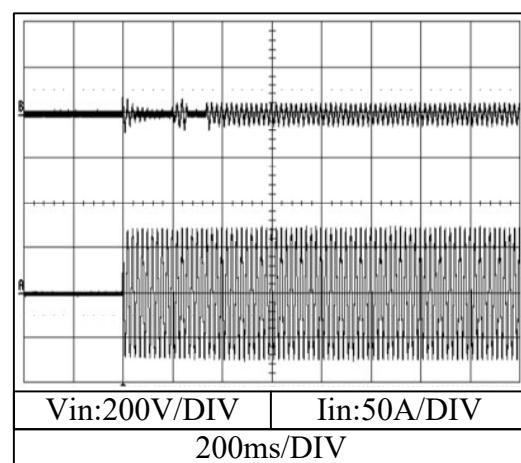
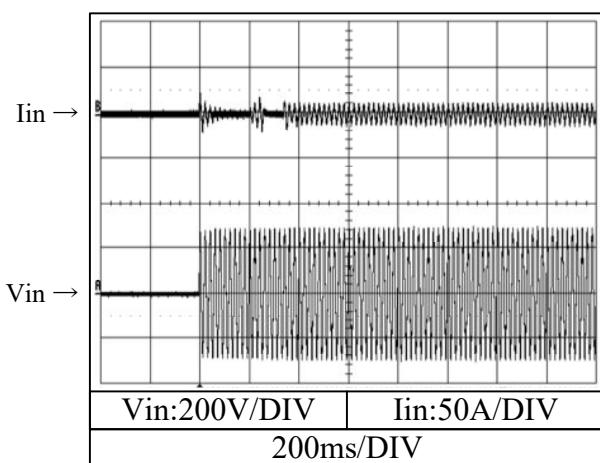
Switch on phase angle  
of input AC voltage  $\phi = 0^\circ$



Switch on phase angle  
of input AC voltage  $\phi = 90^\circ$



48V



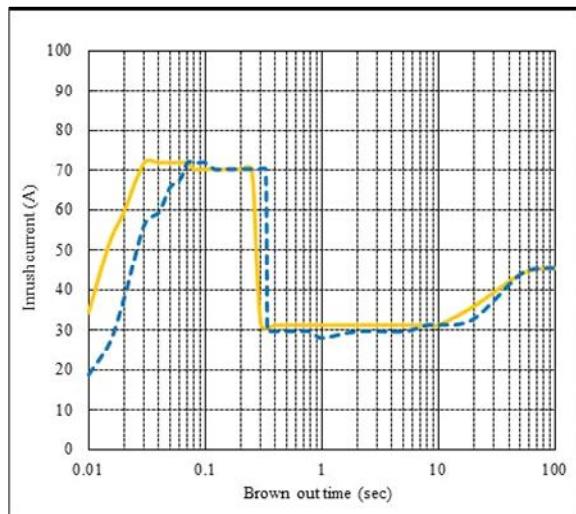
Note : 28V is same as characteristics of 48V

2-12. 瞬停時突入電流特性 Inrush current characteristics at brownout

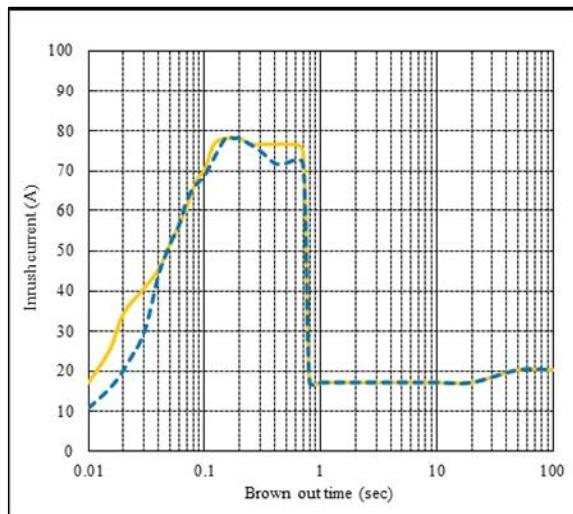
Conditions       $I_o$  : 50% -----  
                   100% ———  
                    $T_{bp}$  : 25 °C

V<sub>in</sub>:100VAC

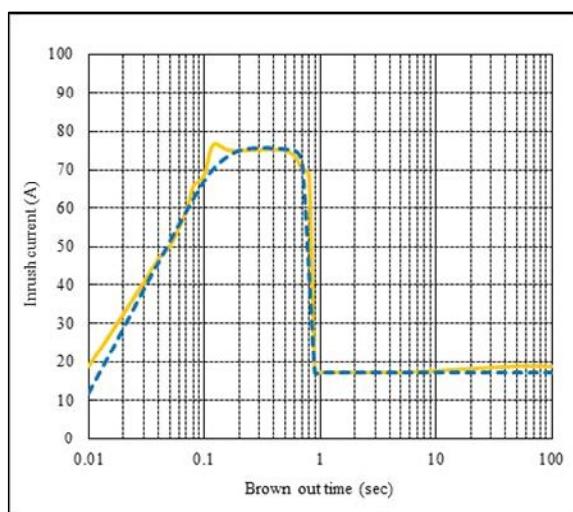
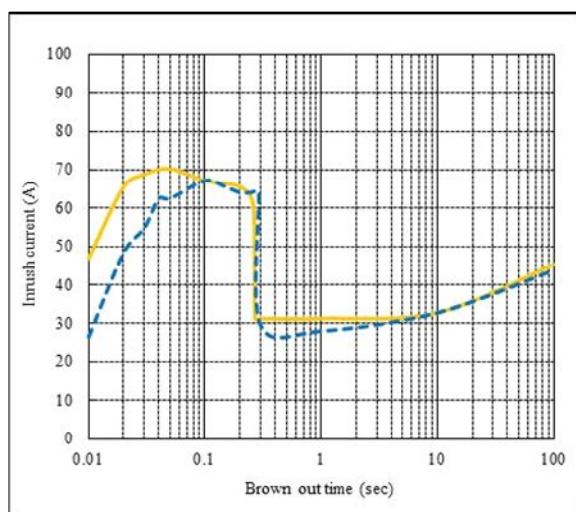
12V



V<sub>in</sub>:200VAC



48V

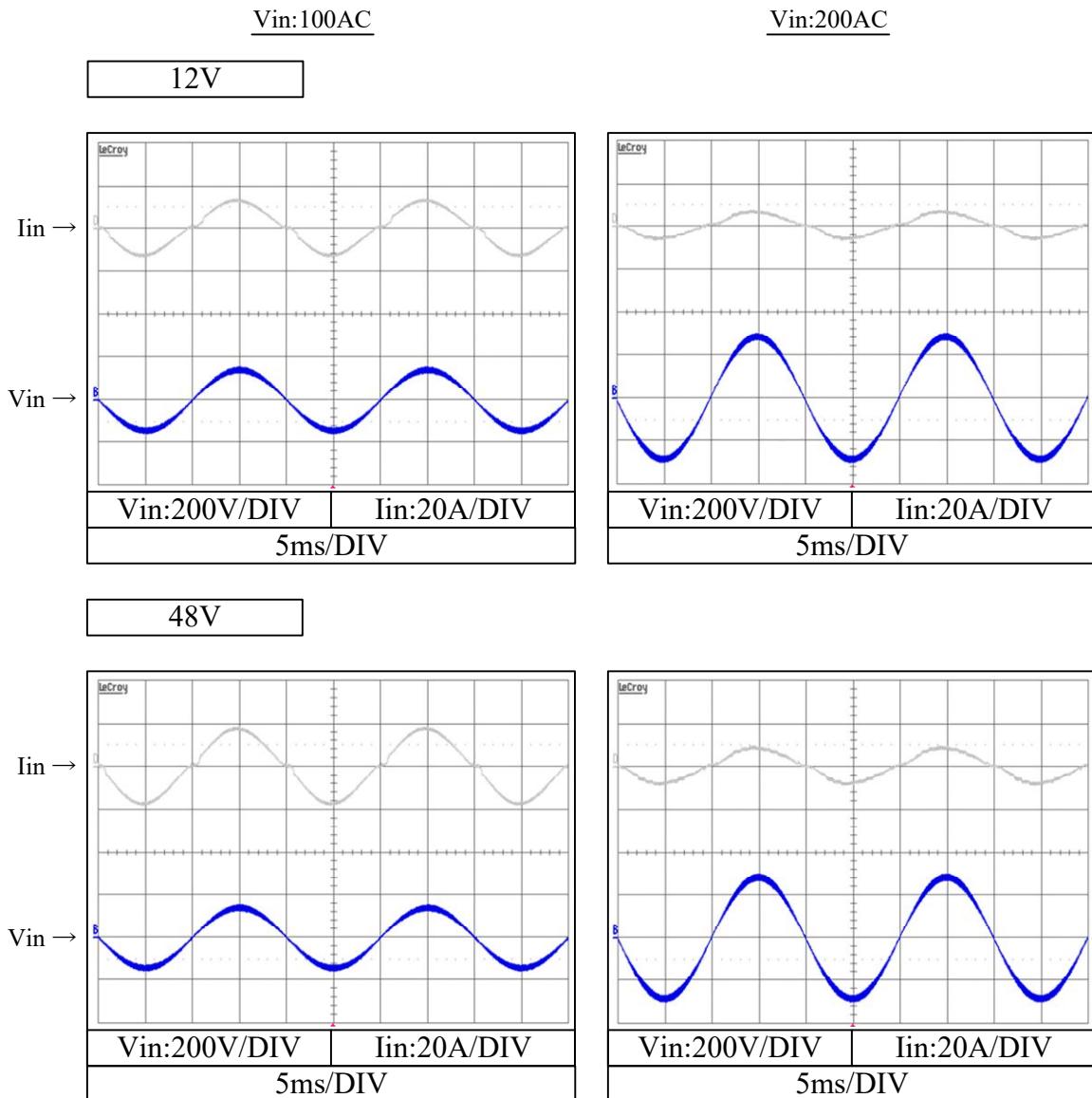


Note : Above data includes secondary inrush current.

: 28V is same as characteristics of 48V

## 2-13. 入力電流波形 Input current waveform

Conditions       $I_o$  : 100%  
                   $T_{bp}$  : 25 °C

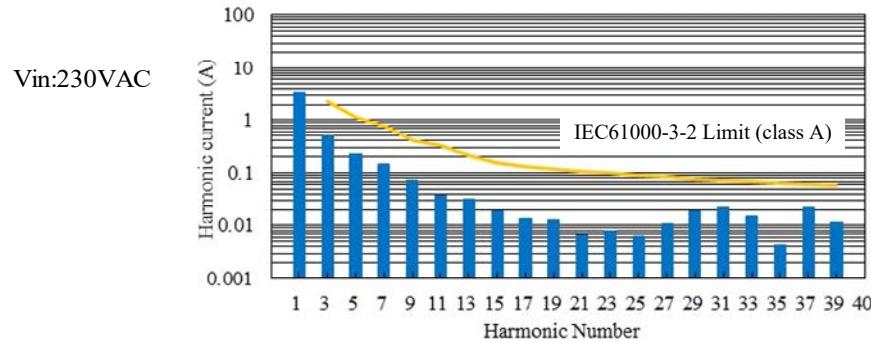
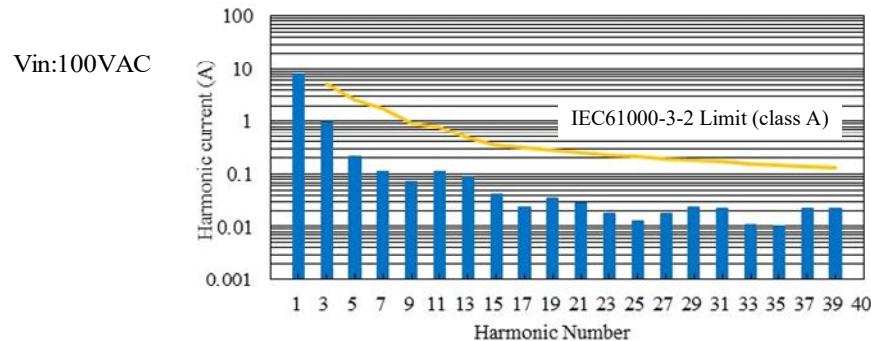


Note : 28V is same as characteristics of 48V

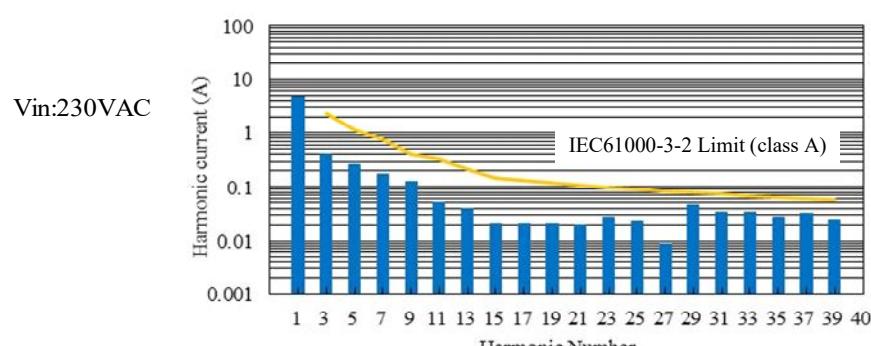
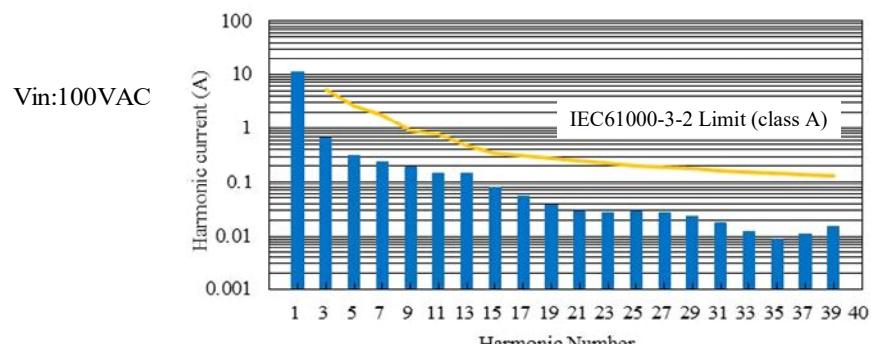
## 2-14. 高調波成分 Input current harmonics

Conditions       $I_o$  : 100%  
 Tbp : 25 °C

12V



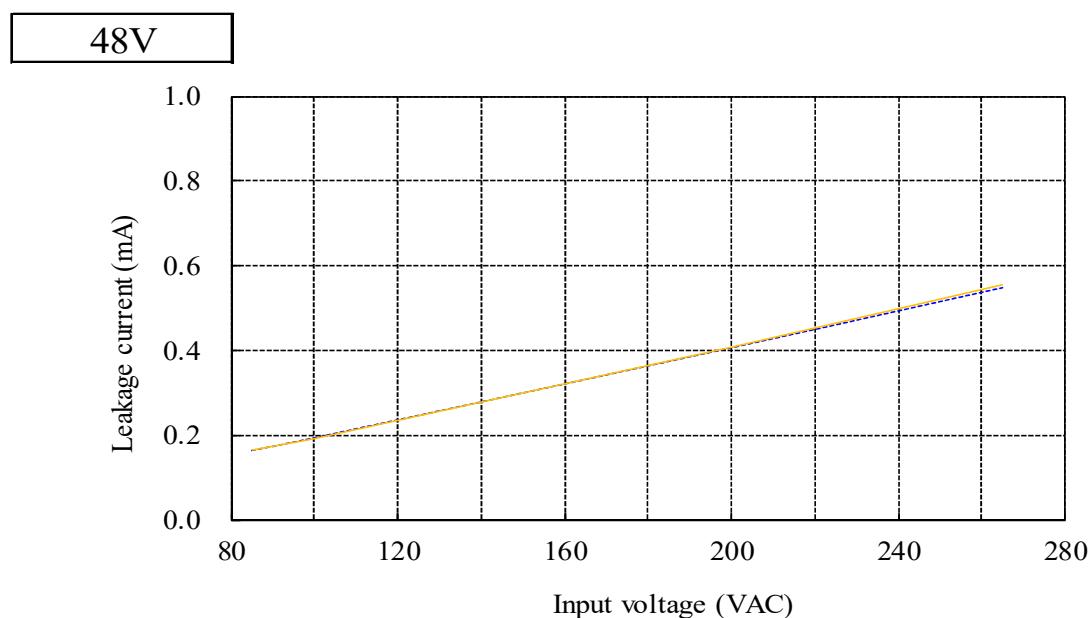
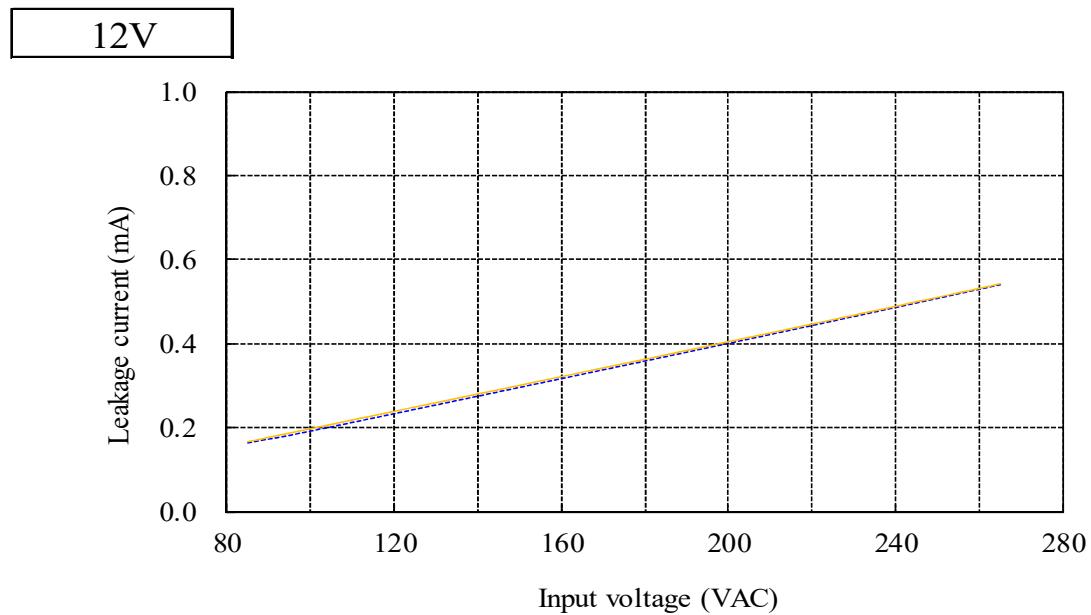
48V



Note : 28V is same as characteristics of 48V

## 2-15. リーク電流特性 Leakage current characteristics

Conditions       $I_o$  : 0% -----  
                  100% ———  
Tbp : 25 °C  
f : 50Hz

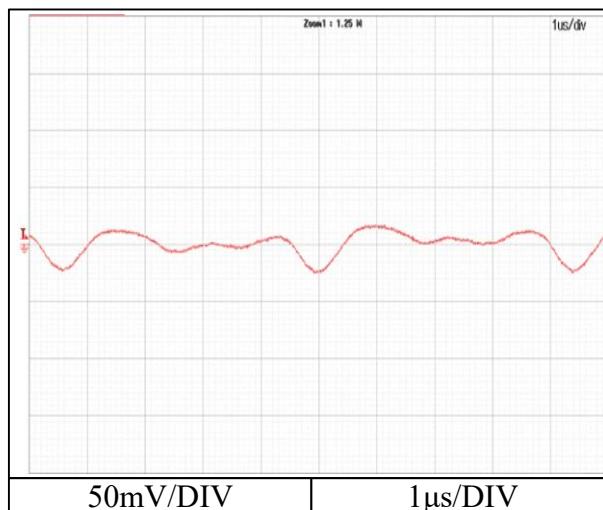


Note : 28V is same as characteristics of 48V

## 2-16. 出力リップル、ノイズ波形 Output ripple and noise waveform

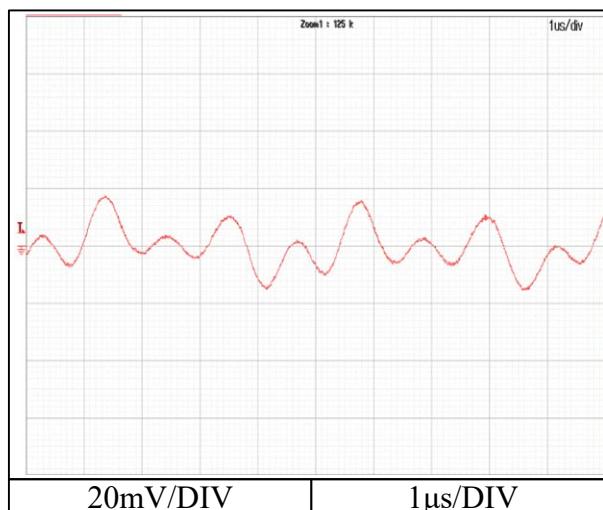
Conditions      Vin : 100VAC  
                  Io : 100%  
                  Tbp : 25 °C

12V



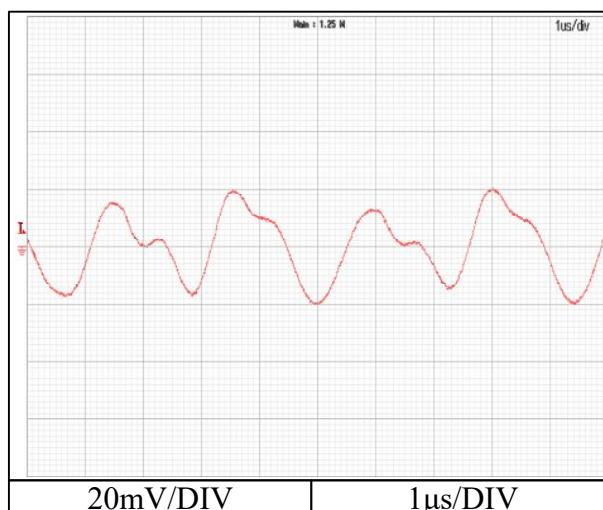
50mV/DIV      1μs/DIV

28V



20mV/DIV      1μs/DIV

48V

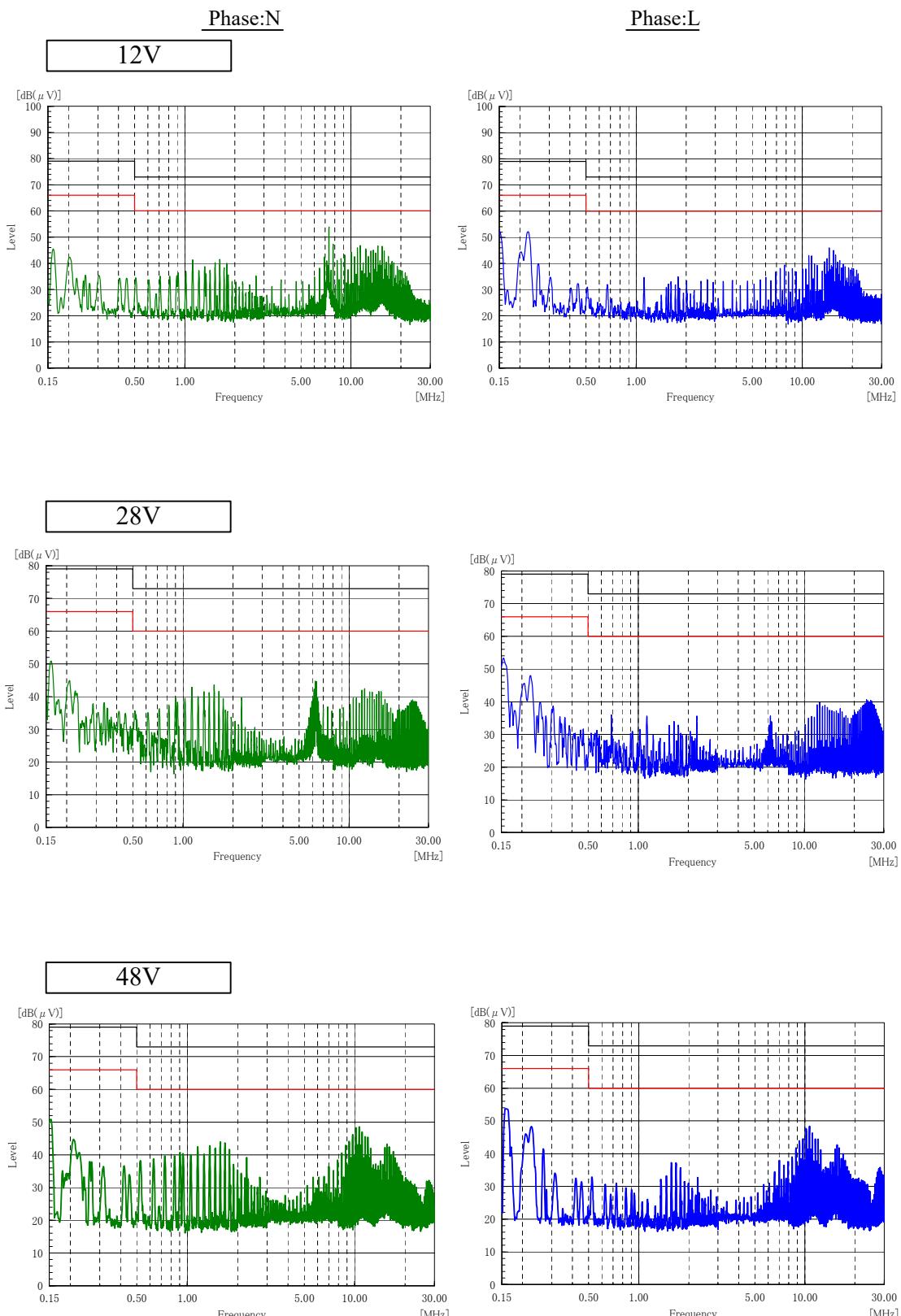


20mV/DIV      1μs/DIV

## 2-17. EMI特性 Electro-Magnetic Interference characteristics

## (a) 雜音端子電圧 (帰還ノイズ) Conducted Emission Noise

Conditions      Vin : 100VAC  
                   Io : 100%  
                   Tbp : 25 °C



2-17. EMI特性 Electro-Magnetic Interference characteristics

(b) 雜音電界強度(輻射ノイズ) Radiated Emission Noise

Conditions Vin : 100VAC

Io : 100%

Tbp : 25 °C

